ESP32-S3 Series

Datasheet

2.4 GHz Wi-Fi + Bluetooth® LE SoC Supporting IEEE 802.11 b/g/n (2.4 GHz Wi-Fi) and Bluetooth® 5 (LE)

Including:

ESP32-S3

ESP32-S3FN8

ESP32-S3R2

ESP32-S3R8

ESP32-S3R8V

ESP32-S3FH4R2



Product Overview

ESP32-S3 is a low-power MCU-based system on a chip (SoC) with integrated 2.4 GHz Wi-Fi and Bluetooth[®] Low Energy (Bluetooth LE). It consists of high-performance dual-core microprocessor (Xtensa[®] 32-bit LX7), a low power coprocessor, a Wi-Fi baseband, a Bluetooth LE baseband, RF module, and numerous peripherals.

The block diagram of the SoC is shown below.

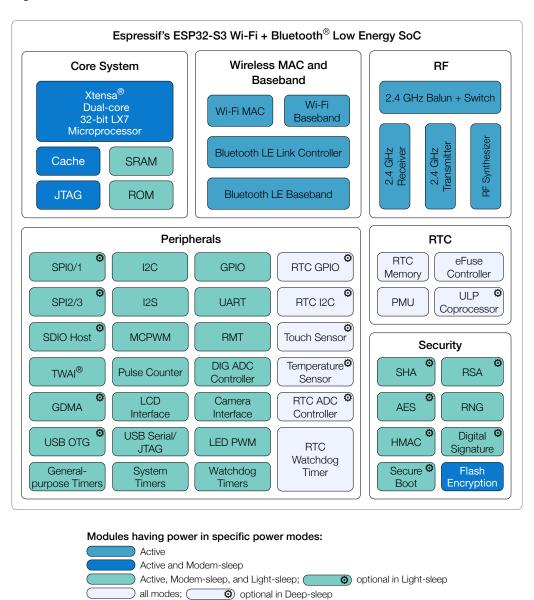


Figure 0-1. ESP32-S3 Block Diagram

Solution Highlights

- A complete Wi-Fi subsystem that complies with IEEE 802.11b/g/n protocol and supports Station, SoftAP, and SoftAP + Station modes
- A Bluetooth LE subsystem that supports features of Bluetooth 5 and Bluetooth mesh
- Xtensa[®] 32-bit LX7 dual-core processor with a five-stage pipeline that operates at up to 240 MHz
 - A 128-bit data bus and dedicated SIMD instructions to provide high computing performance
 - Efficient L1 cache to improve execution of external memory
 - Single-precision floating-point unit (FPU) to accelerate computing
- Highly-integrated RF module that provides industry-leading power and RF performance
- State-of-the-art power management designed for a wide range of applications with its multiple

- low-power modes. The ULP coprocessor can operate in ultra-low-power mode.
- Powerful storage capacities ensured by 512
 KB SRAM and 384 KB ROM on the chip, and SPI, Dual SPI, Quad SPI, Octal SPI, QPI, and OPI interfaces that allow connection to flash and external RAM
- Reliable security features ensured by
 - Cryptographic hardware accelerators that support AES-128/256, Hash, RSA, HMAC, digital signature, and secure boot
 - Random number generator
 - Permission control on accessing internal and external memory
 - External memory encryption and decryption
- Rich set of peripheral interfaces and GPIOs, ideal for various scenarios and complex applications

Features

Wi-Fi

- IEEE 802.11 b/g/n-compliant
- Supports 20 MHz, 40 MHz bandwidth in 2.4 GHz band
- 1T1R mode with data rate up to 150 Mbps
- Wi-Fi Multimedia (WMM)
- TX/RX A-MPDU, TX/RX A-MSDU
- Immediate Block ACK
- Fragmentation and defragmentation
- Automatic Beacon monitoring (hardware TSF)
- 4 × virtual Wi-Fi interfaces
- Simultaneous support for Infrastructure BSS in Station, SoftAP, or Station + SoftAP modes Note that when ESP32-S3 scans in Station

mode, the SoftAP channel will change along with the Station channel

- Antenna diversity
- 802.11mc FTM
- External PA is supported

Bluetooth

- Bluetooth LE: Bluetooth 5, Bluetooth mesh
- High power mode (21 dBm)
- Speed: 125 Kbps, 500 Kbps, 1 Mbps, 2 Mbps
- Advertising extensions
- Multiple advertisement sets
- Channel selection algorithm #2
- Internal co-existence mechanism between Wi-Fi and Bluetooth to share the same antenna

CPU and Memory

- Xtensa[®] dual-core 32-bit LX7 microprocessor, up to 240 MHz
- CoreMark® score:
 - 1 core at 240 MHz: 613.86 CoreMark; 2.56
 CoreMark/MHz
 - 2 cores at 240 MHz: 1181.60 CoreMark;
 4.92 CoreMark/MHz
- 128-bit data bus and SIMD commands
- 384 KB ROM
- 512 KB SRAM
- 16 KB SRAM in RTC
- SPI, Dual SPI, Quad SPI, Octal SPI, QPI and OPI interfaces that allow connection to multiple flash and external RAM
- Flash controller with cache is supported
- Flash in-Circuit Programming (ICP) is supported

Advanced Peripheral Interfaces

- 45 × programmable GPIOs
- Digital interfaces:
 - 4 × SPI
 - 1 x LCD interface (8-bit ~16-bit parallel RGB, I8080 and MOTO6800), supporting conversion between RGB565, YUV422, YUV420 and YUV411
 - 1 x DVP 8-bit ~16-bit camera interface
 - 3 × UART
 - 2 × I2C
 - 2 × I2S
 - 1 × RMT (TX/RX)
 - 1 × pulse counter
 - LED PWM controller, up to 8 channels
 - 1 × full-speed USB OTG

- 1 × USB Serial/JTAG controller
- 2 × MCPWM
- 1 × SDIO host controller with 2 slots
- General DMA controller (GDMA), with 5 transmit channels and 5 receive channels
- 1 x TWAI[®] controller, compatible with ISO 11898-1 (CAN Specification 2.0)
- Analog interfaces:
 - 2 × 12-bit SAR ADCs, up to 20 channels
 - 1 × temperature sensor
 - 14 × touch sensing IOs
- Timers:
 - 4 × 54-bit general-purpose timers
 - 1 × 52-bit system timer
 - 3 × watchdog timers

Low Power Management

- Power Management Unit with five power modes
- Ultra-Low-Power (ULP) coprocessors:
 - ULP-RISC-V coprocessor
 - ULP-FSM coprocessor

Security

- Secure boot
- Flash encryption
- 4-Kbit OTP, up to 1792 bits for users
- Cryptographic hardware acceleration:
 - AES-128/256 (FIPS PUB 197)
 - Hash (FIPS PUB 180-4)
 - RSA
 - Random Number Generator (RNG)
 - HMAC
 - Digital signature

Applications (A Non-exhaustive List)

With low power consumption, ESP32-S3 is an ideal choice for IoT devices in the following areas:

- Smart Home
 - Light control
 - Smart button
 - Smart plug
- Industrial Automation
 - Industrial robot
 - Mesh network
 - Human machine interface (HMI)
- Health Care
 - Health monitor
 - Baby monitor
- Consumer Electronics
 - Smart watch and bracelet
 - Over-the-top (OTT) devices
 - Wi-Fi and bluetooth speaker
 - Logger toys and proximity sensing toys
- Smart Agriculture
 - Smart greenhouse
 - Smart irrigation
 - Agriculture robot
- Retail and Catering

- POS machines
- Service robot
- Audio Device
 - Internet music players
 - Live streaming devices
 - Internet radio players
- Generic Low-power IoT Sensor Hubs
- Generic Low-power IoT Data Loggers
- Cameras for Video Streaming
- USB Devices
- Speech Recognition
- Image Recognition
- Wi-Fi + Bluetooth Networking Card
- Touch Sensing
 - Waterproof design
 - Distance sensing applications
 - Linear slider, wheel slider designs

Note:

ESP32-S3 Touch Sensor has not passed the Conducted Susceptibility (CS) test for now, and thus has limited application scenarios.

Note:

Check the link or the QR code to make sure that you use the latest version of this document: https://www.espressif.com/documentation/esp32-s3_datasheet_en.pdf



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1 ESP32-S3 Series Comparison

1.1 ESP32-S3 Series Nomenclature

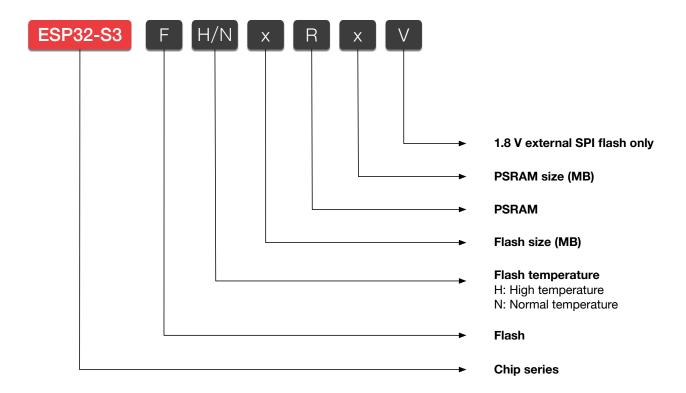


Figure 1-1. ESP32-S3 Series Nomenclature

1.2 Comparison

Table 1-1. ESP32-S3 Series Comparison

Ordering Code	In-package flash	In-package PSRAM	Ambient Temperature (°C)	SPI Voltage
ESP32-S3	_	_	-40 ∼ 105	3.3 V/1.8 V
ESP32-S3FN8	8 MB (Quad SPI)	_	-40 ∼ 85	3.3 V
ESP32-S3R2	_	2 MB (Quad SPI)	-40 ~ 85	3.3 V
ESP32-S3R8 ¹	_	8 MB (Octal SPI) ²	-40 ∼ 65	3.3 V
ESP32-S3R8V ¹	_	8 MB (Octal SPI) ²	-40 ∼ 65	1.8 V
ESP32-S3FH4R2 ³	4 MB (Quad SPI)	2 MB (Quad SPI)	-40 ~ 105	3.3 V

¹ For ESP32-S3R8 and ESP32-S3R8V chips, if the PSRAM ECC function is enabled, the maximum ambient temperature can be improved to 85 °C, while the usable size of PSRAM will be reduced by 1/16.

 $^{^2}$ Octal SPI occupies five more GPIOs (GPIO33 \sim GPIO37) than Quad SPI.

³ The ESP32-S3FH4R2 chip is still in **sample status**.

2 Pin Definition

2.1 Pin Layout

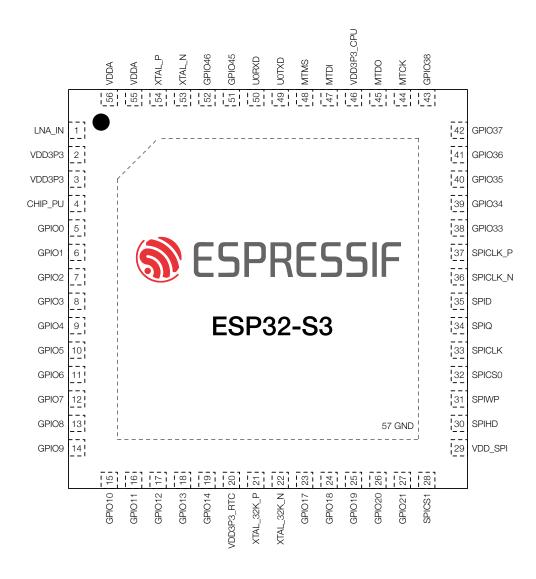


Figure 2-1. ESP32-S3 Pin Layout (Top View)

N

Pin Definition

2.2 Pin Description

Table 2-1. Pin Description

Name	No.	Туре	Power Domain	Function									
LNA_IN	1	1/0	_	Low Noise Ampli	Low Noise Amplifier (RF LNA) input and output signal								
VDD3P3	2	P_A	_	Analog power supply									
VDD3P3	3	P_A	_	Analog power su	pply								
				High: on, enables	High: on, enables the chip.								
CHIP_PU	4	I	VDD3P3_RTC	Low: off, the chip	powers of	f.							
				Note: Do not leav	ve the CHIF	P_PU pin floati	ng.						
GPIO0	5	I/O/T	VDD3P3_RTC	RTC_GPIO0,	GPIO0								
GPIO1	6	I/O/T	VDD3P3_RTC	RTC_GPIO1,	GPIO1,	TOUCH1,	ADC1_CH0						
GPIO2	7	I/O/T	VDD3P3_RTC	RTC_GPIO2,	GPIO2,	TOUCH2,	ADC1_CH1						
GPIO3	8	I/O/T	VDD3P3_RTC	RTC_GPIO3,	GPIO3,	TOUCH3,	ADC1_CH2						
GPIO4	9	I/O/T	VDD3P3_RTC	RTC_GPIO4,	GPIO4,	TOUCH4,	ADC1_CH3						
GPIO5	10	I/O/T	VDD3P3_RTC	RTC_GPIO5,	GPIO5,	TOUCH5,	ADC1_CH4						
GPIO6	11	I/O/T	VDD3P3_RTC	RTC_GPIO6,	GPIO6,	TOUCH6,	ADC1_CH5						
GPIO7	12	I/O/T	VDD3P3_RTC	RTC_GPIO7,	GPIO7,	TOUCH7,	ADC1_CH6						
GPIO8	13	I/O/T	VDD3P3_RTC	RTC_GPIO8,	GPIO8,	TOUCH8,	ADC1_CH7,	SUBSPICS1					
GPIO9	14	I/O/T	VDD3P3_RTC	RTC_GPIO9,	GPIO9,	TOUCH9,	ADC1_CH8,	SUBSPIHD,	FSPIHD				
GPIO10	15	I/O/T	VDD3P3_RTC	RTC_GPIO10,	GPIO10,	TOUCH10,	ADC1_CH9,	FSPIIO4,	SUBSPICSO,	FSPICS0			
GPIO11	16	I/O/T	VDD3P3_RTC	RTC_GPIO11,	GPIO11,	TOUCH11,	ADC2_CH0,	FSPIIO5,	SUBSPID,	FSPID			
GPIO12	17	I/O/T	VDD3P3_RTC	RTC_GPIO12,	GPIO12,	TOUCH12,	ADC2_CH1,	FSPIIO6,	SUBSPICLK,	FSPICLK			
GPIO13	18	I/O/T	VDD3P3_RTC	RTC_GPIO13,	GPIO13,	TOUCH13,	ADC2_CH2,	FSPIIO7,	SUBSPIQ,	FSPIQ			
GPIO14	19	I/O/T	VDD3P3_RTC	RTC_GPIO14,	GPIO14,	TOUCH14,	ADC2_CH3,	FSPIDQS,	SUBSPIWP,	FSPIWP			
VDD3P3_RTC	20	P_A	-	Analog power su	pply								
XTAL_32K_P	21	I/O/T	VDD3P3_RTC	RTC_GPIO15,	GPIO15,	U0RTS,	ADC2_CH4,	XTAL_32K_P					
XTAL_32K_N	22	I/O/T	VDD3P3_RTC	RTC_GPIO16,	GPIO16,	U0CTS,	ADC2_CH5,	XTAL_32K_N					
GPIO17	23	I/O/T	VDD3P3_RTC	RTC_GPIO17,	GPIO17,	U1TXD,	ADC2_CH6						

Name	No.	Туре	Power Domain	Function					
GPIO18	24	I/O/T	VDD3P3_RTC	RTC_GPIO18,	GPIO18,	U1RXD,	ADC2_CH7,	CLK_OUT3	
GPIO19	25	I/O/T	VDD3P3_RTC	RTC_GPIO19,	GPIO19,	U1RTS,	ADC2_CH8,	CLK_OUT2,	USB_D-
GPIO20	26	I/O/T	VDD3P3_RTC	RTC_GPIO20,	GPIO20,	U1CTS,	ADC2_CH9,	CLK_OUT1,	USB_D+
GPIO21	27	I/O/T	VDD3P3_RTC	RTC_GPIO21,	GPIO21				
SPICS1	28	I/O/T	VDD_SPI	SPICS1,	GPIO26				
VDD_SPI	29	P_D	_	Output power su	pply: 1.8 V	or VDD3P3_R	RTC		
SPIHD	30	I/O/T	VDD_SPI	SPIHD,	GPIO27				
SPIWP	31	I/O/T	VDD_SPI	SPIWP,	GPIO28				
SPICS0	32	I/O/T	VDD_SPI	SPICS0,	GPIO29				
SPICLK	33	I/O/T	VDD_SPI	SPICLK,	GPIO30				
SPIQ	34	I/O/T	VDD_SPI	SPIQ,	GPIO31				
SPID	35	I/O/T	VDD_SPI	SPID,	GPIO32				
SPICLK_N	36	I/O/T	VDD_SPI	SPICLK_N_DIFF,	GPIO48,	SUBSPICLK_	_N_DIFF		
SPICLK_P	37	I/O/T	VDD_SPI	SPICLK_P_DIFF,	GPI047,	SUBSPICLK	_P_DIFF		
GPIO33	38	I/O/T	VDD3P3_CPU / VDD_SPI	SPIIO4,	GPIO33,	FSPIHD,	SUBSPIHD		
GPIO34	39	I/O/T	VDD3P3_CPU / VDD_SPI	SPIIO5,	GPIO34,	FSPICS0,	SUBSPICS0		
GPIO35	40	I/O/T	VDD3P3_CPU / VDD_SPI	SPIIO6,	GPIO35,	FSPID,	SUBSPID		
GPIO36	41	I/O/T	VDD3P3_CPU / VDD_SPI	SPIIO7,	GPIO36,	FSPICLK,	SUBSPICLK		
GPIO37	42	I/O/T	VDD3P3_CPU / VDD_SPI	SPIDQS,	GPIO37,	FSPIQ,	SUBSPIQ		
GPIO38	43	I/O/T	VDD3P3_CPU	GPIO38,	FSPIWP,	SUBSPIWP			
MTCK	44	I/O/T	VDD3P3_CPU	MTCK,	GPIO39,	CLK_OUT3,	SUBSPICS1		
MTDO	45	I/O/T	VDD3P3_CPU	MTDO,	GPI040,	CLK_OUT2			
VDD3P3_CPU	46	P_D	_	Input power supply for CPL		IO			
MTDI	47	I/O/T	VDD3P3_CPU	MTDI,	GPI041,	CLK_OUT1			
MTMS	48	I/O/T	VDD3P3_CPU	MTMS,	GPIO42				
U0TXD	49	I/O/T	VDD3P3_CPU	U0TXD,	GPIO43,	CLK_OUT1			
U0RXD	50	I/O/T	VDD3P3_CPU	U0RXD,	GPIO44,	CLK_OUT2			
GPIO45	51	I/O/T	VDD3P3_CPU	GPIO45					
GPIO46	52	I/O/T	VDD3P3_CPU	GPIO46		·			

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Pin Definition

Name	No.	Type	Power Domain	Function
XTAL_N	53	_	_	External crystal output
XTAL_P	54	_	_	External crystal input
VDDA1	55	P_A	_	Analog power supply
VDDA2	56	P_A	_	Analog power supply
GND	57	G	_	Ground

Pin Definition

¹ P: power pin; P_A : analog power pin; P_D : digital power pin; I: input; O: output; T: high impedance.

² Pin functions in bold font are the default pin functions in SPI Boot mode. For pins No.38 \sim 42, the default function is decided by eFuse bit.

³ Power supply for GPIO33, GPIO34, GPIO35, GPIO36 and GPIO37 is configurable to be either VDD3P3_CPU (default) or VDD_SPI.

⁴ For ESP32-S3R8V chip, as the VDD_SPI voltage has been set to 1.8 V, the working voltage for GPIO47 and GPIO48 would also be 1.8 V, which is different from other GPIOs.

⁵ The pin function in this table refers only to some fixed settings and do not cover all cases for signals that can be input and output through the GPIO matrix. For more information on the GPIO matrix, please refer to ESP32-S3 Technical Reference Manual.

Pin Name Description 2.3

The explanation of each pin name is briefly described below.

Table 2-2. Pin Name Description

Pin Name	Description							
	General-purpose input and output (x is GPIO number). GPIO pins can							
GPIOx	be assigned various functions, including digital and analog functions. For							
	more information on digital functions, please refer to Table 2-4.							
SPIx	In-package flash/PSRAM and external flash/RAM interface (x is CLK, CS0,							
SPIX	CS1, D, Q, WP, HD, IO4~7 or DQS).							
VTAL 201/ D/NI	32 KHz external clock input/output (connecting to ESP32-S3's oscillator).							
XTAL_32K_P/N	P/N means differential clock positive/negative.							
VTAL D/NI	External clock input/output (connecting to ESP32-S3's oscillator). P/N							
XTAL_P/N	means differential clock positive/negative.							
U0RXD/U0TXD	UART0 receive/transmit signals.							
MTCK/MTDO/MTDI/MTMS	JTAG interface signals.							
LNA_IN	Low-Noise Amplifier (RF LNA) input/output signals.							
CHIP_PU	Chip power up pin.							
GND	External ground connection.							
VDDA	Power supply for analog domain.							
VDD3P3	Power supply for analog domain.							
VDD3P3_RTC	Power supply for RTC digital domain.							
VDD3P3_CPU	Power supply for digital domain.							
VDD_SPI	Power supply for SPI IOs.							

Function Name Description 2.4

The explanation of each function name is briefly described below.

Table 2-3. Function Name Description

Function Name	Description					
RTC_GPIOx	RTC domain GPIO function for low power management.					
TOUCHx	Analog function for touch sensing.					
ADCx_CHy	Analog to digital conversion channel (x is ADC number, y is channel number).					
SUBSPIx	Sub-SPI0/1 bus, differing from SPIx bus (x is CLK, CS0, CS1, D, Q, WP or HD),					
JODSFIX	used for different voltage level of flash and PSRAM					
FSPIx	8-line Fast-SPI2 bus function (x is CLK, CS0, CS1, D, Q, WP, HD, IO4~7 or DQS)					
SPIx	SPI0/1 bus function (x is CLK, CS0, CS1, D, Q, WP, HD, IO4~7 or DQS)					
UxRTS/UxCTS	UARTx hardware flow control signals (x is UART number).					
U1RXD/U1TXD	UART1 receive/transmit signals.					
CLK_OUTx	Clock output for debug (x is clock number).					
LICE D /LICE D.	USB OTG and USB Serial/JTAG function. USB signal is a differential signal					
USB_D-/USB_D+	transmitted over a pair of D+ and D- wires.					
SPICLK_N/P_DIFF	Serial peripheral interface differential clock negative/positive.					

Pin Definition

2.5 GPIO Functions

ESP32-S3 has 45 GPIO pins (numbering 22-25 is not used) which can be assigned various functions as listed in Table 2-4. The functions listed here are digital functions (F0-F4). RTC functions and analog functions can be found in Table 2-1.

Table 2-4. GPIO Functions

GPIO	Pin Name	F0	Туре	F1	Туре	F2	Туре	F3	Туре	F4	Туре	At Reset	After Reset	Notes
0	GPIO0	GPIO0	I/O/T	GPI00	I/O/T	-	-	-	-	-	-	IE1, WPU1	IE1, WPU1	R
1	GPIO1	GPIO1	I/O/T	GPIO1	I/O/T	-	-	-	-	-	-	IE1	IE1	R, G
2	GPIO2	GPIO2	I/O/T	GPIO2	I/O/T	-	-	-	-	-	-	IE1	IE1	R, G
3	GPIO3	GPIO3	I/O/T	GPIO3	I/O/T	-	-	-	-	-	-	IE1	IE1	R, G
4	GPIO4	GPIO4	I/O/T	GPIO4	I/O/T	-	-	-	-	-	-	IE0	IE0	R, G
5	GPIO5	GPIO5	I/O/T	GPIO5	I/O/T	-	-	-	-	-	-	IE0	IE0	R, G
6	GPIO6	GPIO6	I/O/T	GPIO6	I/O/T	-	-	-	-	-	-	IE0	IE0	R, G
7	GPIO7	GPIO7	I/O/T	GPIO7	I/O/T	-	-	-	-	-	-	IE0	IE0	R, G
8	GPIO8	GPIO8	I/O/T	GPIO8	I/O/T	-	-	SUBSPICS1	O/T	-	-	IE0	IE0	R, G
9	GPIO9	GPIO9	I/O/T	GPIO9	I/O/T	-	-	SUBSPIHD	I1/O/T	FSPIHD	I1/O/T	IE0	IE1	R, G
10	GPIO10	GPIO10	I/O/T	GPIO10	I/O/T	FSPIIO4	I1/O/T	SUBSPICS0	O/T	FSPICS0	I1/O/T	IE0	IE1	R, G
11	GPIO11	GPIO11	I/O/T	GPIO11	I/O/T	FSPIIO5	I1/O/T	SUBSPID	I1/O/T	FSPID	I1/O/T	IE0	IE1	R, G
12	GPIO12	GPIO12	I/O/T	GPIO12	I/O/T	FSPIIO6	I1/O/T	SUBSPICLK	O/T	FSPICLK	I1/O/T	IE0	IE1	R, G
13	GPIO13	GPIO13	I/O/T	GPIO13	I/O/T	FSPIIO7	I1/O/T	SUBSPIQ	I1/O/T	FSPIQ	I1/O/T	IE0	IE1	R, G
14	GPIO14	GPIO14	I/O/T	GPIO14	I/O/T	FSPIDQS	O/T	SUBSPIWP	I1/O/T	FSPIWP	I1/O/T	IE0	IE1	R, G
15	XTAL_32K_P	GPIO15	I/O/T	GPIO15	I/O/T	U0RTS	0	-	-	-	-	IE0	IE0	R, G
16	XTAL_32K_N	GPIO16	I/O/T	GPIO16	I/O/T	U0CTS	l1	-	-	-	-	IE0	IE0	R, G
17	GPIO17	GPIO17	I/O/T	GPIO17	I/O/T	U1TXD	0	-	-	-	-	IE0	IE1	R, G
18	GPIO18	GPIO18	I/O/T	GPIO18	I/O/T	U1RXD	I1	CLK_OUT3	0	-	-	IE0	IE1	R, G
19	GPIO19	GPIO19	I/O/T	GPIO19	I/O/T	U1RTS	0	CLK_OUT2	0	-	-	IE0	IE0	R, G
20	GPIO20	GPIO20	I/O/T	GPIO20	I/O/T	U1CTS	I1	CLK_OUT1	0	-	-	IE0	IE0	R, G
21	GPIO21	GPIO21	I/O/T	GPIO21	I/O/T	-	-	-	-	-	-	IE0	IE0	R
26	SPICS1	SPICS1	O/T	GPIO26	I/O/T	-	-	-	-	-	-	IE1, WPU1	IE1, WPU1	-
27	SPIHD	SPIHD	I1/O/T	GPIO27	I/O/T	-	-	-	-	-	-	IE1, WPU1	IE1, WPU1	-
28	SPIWP	SPIWP	I1/O/T	GPIO28	I/O/T	-	-	-	-	-	-	IE1, WPU1	IE1, WPU1	-

GPIO	Pin Name	F0	Туре	F1	Туре	F2	Туре	F3	Туре	F4	Туре	At Reset	After Reset	Notes
29	SPICS0	SPICS0	O/T	GPIO29	I/O/T	-	-	-	-	-	-	IE1, WPU1	IE1, WPU1	-
30	SPICLK	SPICLK	O/T	GPIO30	I/O/T	-	-	-	-	-	-	IE1, WPU1	IE1, WPU1	-
31	SPIQ	SPIQ	I1/O/T	GPIO31	I/O/T	-	-	-	-	-	-	IE1, WPU1	IE1, WPU1	-
32	SPID	SPID	I1/O/T	GPIO32	I/O/T	-	-	-	-	-	-	IE1, WPU1	IE1, WPU1	-
33	GPIO33	GPIO33	I/O/T	GPIO33	I/O/T	FSPIHD	I1/O/T	SUBSPIHD	I1/O/T	SPIIO4	I1/O/T	IE0	IE1	-
34	GPIO34	GPIO34	I/O/T	GPIO34	I/O/T	FSPICS0	I1/O/T	SUBSPICS0	O/T	SPIIO5	I1/O/T	IE0	IE1	-
35	GPIO35	GPIO35	I/O/T	GPIO35	I/O/T	FSPID	I1/O/T	SUBSPID	I1/O/T	SPIIO6	I1/O/T	IE0	IE1	-
36	GPIO36	GPIO36	I/O/T	GPIO36	I/O/T	FSPICLK	I1/O/T	SUBSPICLK	O/T	SPIIO7	I1/O/T	IE0	IE1	-
37	GPIO37	GPIO37	I/O/T	GPIO37	I/O/T	FSPIQ	I1/O/T	SUBSPIQ	I1/O/T	SPIDQS	10/O/T	IE0	IE1	-
38	GPIO38	GPIO38	I/O/T	GPIO38	I/O/T	FSPIWP	I1/O/T	SUBSPIWP	I1/O/T	-	-	IE0	IE1	-
39	MTCK	MTCK	I1	GPIO39	I/O/T	CLK_OUT3	0	SUBSPICS1	O/T	-	-	IE0	IE1, or IE1&WPU1	-
40	MTDO	MTDO	O/T	GPIO40	I/O/T	CLK_OUT2	0	-	-	-	-	IE0	IE1	-
41	MTDI	MTDI	l1	GPIO41	I/O/T	CLK_OUT1	0	-	-	-	-	IE0	IE1	-
42	MTMS	MTMS	I1	GPIO42	I/O/T	-	-	-	-	-	-	IE0	IE1	-
43	U0TXD	U0TXD	0	GPIO43	I/O/T	CLK_OUT1	0	-	-	-	-	IE1, WPU1	IE1, WPU1	-
44	U0RXD	U0RXD	I1	GPIO44	I/O/T	CLK_OUT2	0	-	-	-	-	IE1, WPU1	IE1, WPU1	-
45	GPIO45	GPIO45	I/O/T	GPIO45	I/O/T	-	-	-	-	-	-	IE1, WPD1	IE1, WPD1	-
46	GPIO46	GPIO46	I/O/T	GPIO46	I/O/T	-	-	-	-	-	-	IE1, WPD1	IE1, WPD1	-
47	SPICLK_P	SPICLK_P_DIFF	O/T	GPIO47	I/O/T	SUBSPI- CLK_P_DIFF	O/T	-	-	-	-	IE1	IE1	-
48	SPICLK_N	SPICLK_N_DIFF	O/T	GPIO48	I/O/T	SUBSPI- CLK_N_DIFF	O/T	-	-	-	-	IE1	IE1	-

Please refer to the next page for more information on GPIO functions.

Type

Each digital function (F_n , n=0~4) is associated with a "Type". The description of "Type" is as follows:

- O: Output only.
- O/T: The signal can be output or high-impedance.
- I/O/T: The signal can be input, output, and high-impedance.
- I1: Input only. If the pin is assigned a function other than Fn, the input signal of Fn is always "1".
- 11/O/T: The signal can be input, output, and high-impedance. If F_n is not selected, the input signal of F_n is always "1".
- 10/O/T: The signal can be input, output, and high-impedance. If F_n is not selected, the input signal of F_n is always "0".

At Reset/After Reset

The default configuration of each pin at reset and after reset:

- IEO input disabled
- IE1 input enabled
- IE1, WPD1 input enabled, internal weak pull-down resistor enabled
- IE1, WPU1 input enabled, internal weak pull-up resistor enabled
- IE1, or IE1&WPU1 When the value of eFuse bit EFUSE_DIS_PAD_JTAG is
 - 1, the MTCK pin floats after chip reset (IE1)
 - 0, the MTCK pin connects to internal weak pull-up resistor after chip reset (IE1&WPU1)

Drive Strength

- The default drive strength of GPIO19 ~ 20 is 2'd3 (~40 mA).
- The default drive strength of other pins is 2'd2 (~20 mA).

Notes

- R These pins have RTC or analog functions.
- **G** These pins have glitches during power-up. See details in Table 2-5.

Table 2-5. Power-Up Glitches on Pins

Pin	Glitch ¹	Typical Time Period (μ s)
GPIO1	Low-level glitch	60
GPIO2	Low-level glitch	60
GPIO3	Low-level glitch	60
GPIO4	Low-level glitch	60
GPIO5	Low-level glitch	60
GPIO6	Low-level glitch	60
GPI07	Low-level glitch	60
GPIO8	Low-level glitch	60
GPIO9	Low-level glitch	60

GPIO10	Low-level glitch	60
GPIO11	Low-level glitch	60
GPIO12	Low-level glitch	60
GPIO13	Low-level glitch	60
GPIO14	Low-level glitch	60
XTAL_32K_P	Low-level glitch	60
XTAL_32K_N	Low-level glitch	60
GPIO17	Low-level glitch	60
GPIO18	Low-level glitch	60
GFIOTO	High-level glitch	60
GPIO19	Low-level glitch	60
GFIOT9	High-level glitch ²	60
GPIO20	Pull-down glitch	60
GI 1020	High-level glitch ²	60

¹ Low-level glitch: the pin is at a low level output status during the time period; High-level glitch: the pin is at a high level output status during the time period; Pull-down glitch: the pin is at an internal weak pulled-down status during the time period; Pull-up glitch: the pin is at an internal weak pulled-up status during the time period. Please refer to Table 4-4 for detailed parameters about low/high-level and pull-down/up.

2.6 Pin-to-Pin Mapping Between Chip and In-Package Flash/PSRAM

Table 2-6 lists the pin-to-pin mapping between the chip and the in-package flash/PSRAM. The chip pins listed here are not recommended for other usage. For the data port connection between ESP32-S3 and external flash please refer to Section 3.5.2.

Table 2-6. Pin-to-Pin Mapping Between Chip and In-Package Flash/PSRAM

ESP32-S3FN8 (8 MB) / ESP32-S3FH4R2 (4 MB)	In-Package Flash (Quad SPI)
SPICLK	CLK
SPICS0	CS#
SPID	DI
SPIQ	DO
SPIWP	WP#
SPIHD	HOLD#
ESP32-S3R2 / ESP32-S3FH4R2	In-package PSRAM (2 MB, Quad SPI)
SPICLK	CLK
SPICS1	CE#
SPID	SI/SIO0
SPIQ	SO/SIO1
SPIWP	SIO2

 $^{^2}$ GPIO19 and GPIO20 pins both have two high-level glitches during chip power-up, each lasting for about 60 μ s. The total duration for the glitches and the delay are 3.2 ms and 2 ms respectively for GPIO19 and GPIO20.

SPIHD	SIO3
ESP32-S3R8 / ESP32-S3R8V	In-package PSRAM (8 MB, Octal SPI)
SPICLK	CLK
SPICS1	CE#
SPID	DQ0
SPIQ	DQ1
SPIWP	DQ2
SPIHD	DQ3
GPIO33	DQ4
GPIO34	DQ5
GPIO35	DQ6
GPIO36	DQ7
GPIO37	DQS/DM

2.7 Power Scheme

ESP32-S3 has six input power pins:

- VDDA1
- VDDA2
- VDD3P3 × 2
- VDD3P3 RTC
- VDD3P3_CPU

And one input/output power pin:

• VDD SPI

VDDA1, VDDA2, and the two VDD3P3 pins are the input power supply for the analog domain.

VDD_SPI can be an input power supply or output power supply. It can be powered by Flash Voltage Regulator (nominal 1.8 V) or by VDD3P3_RTC via R_{SPI} (nominal 3.3 V). As the in-package flash/PSRAM in ESP32-S3FN8, ESP32-S3R2, and ESP32-S3R8 operates at 3.3 V, VDD_SPI must be powered by VDD3P3_RTC via R_{SPI} . Software can power off VDD_SPI to minimize current leakage of flash in Deep-sleep mode.

VDD3P3_RTC is the input power supply for Low Power Voltage Regulator that powers the RTC domain.

VDD3P3_CPU and VDD3P3_RTC power Digital System Voltage Regulator at the same time that further powers the Digital System domain.

VDD3P3_RTC is the input power supply for RTC IO.

VDD3P3_CPU is the input power supply for Digital IO.

VDD_SPI is the input power supply for SPI IO.

Either VDD_SPI or VDD3P3_CPU can be selected as the input power supply for SPI/Digital IO.

The power scheme diagram is shown in Figure 2-2.

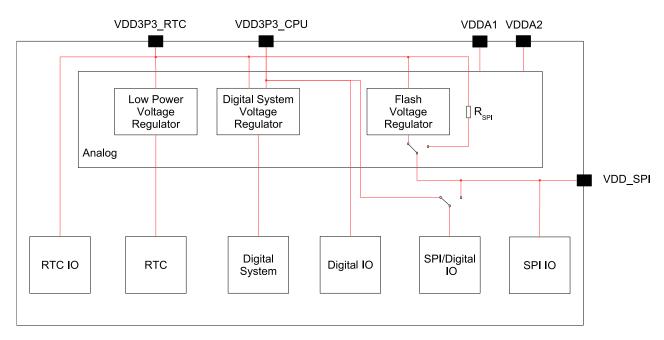


Figure 2-2. ESP32-S3 Power Scheme

Notes on CHIP_PU:

Figure 2-3 shows the power-up and reset timing of ESP32-S3 series. Details about the parameters are listed in Table 2-7.

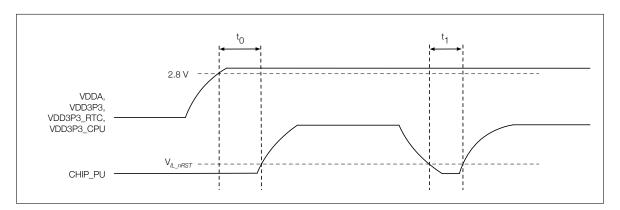


Figure 2-3. ESP32-S3 Power-up and Reset Timing

Table 2-7. Description of ESP32-S3 Power-up and Reset Timing Parameters

Parameter	Description		
+	Time between bringing up the VDDA, VDD3P3, VDD3P3_RTC, and		
t_0	VDD3P3_CPU rails, and activating CHIP_PU		
+	Duration of CHIP_PU signal level $<$ V_{IL_nRST} (refer to its value in		
ι ₁	Table 4-4) to reset the chip	50	

2.8 Strapping Pins

ESP32-S3 has four strapping pins:

- GPI00
- GPIO45
- GPIO46
- GPIO3

Software can read the values of corresponding bits from register "GPIO_STRAPPING".

During the chip's system reset (power-on-reset, RTC watchdog reset, brownout reset, analog super watchdog reset, and crystal clock glitch detection reset), the latches of the strapping pins sample the voltage level as strapping bits of "0" or "1", and hold these bits until the chip is powered down or shut down.

GPIO0, GPIO45 and GPIO46 are connected to the chip's internal weak pull-up/pull-down during the chip reset. Consequently, if they are unconnected or the connected external circuit is high-impedance, the internal weak pull-up/pull-down will determine the default input level of these strapping pins.

GPIO3 is floating by default. Its strapping value can be configured to determine the source of the JTAG signal inside the CPU, as shown in Table 2-9. In this case, the strapping value is controlled by the external circuit that cannot be in a high impedance state. Table 2-8 shows more configuration combinations of EFUSE_DIS_USB_JTAG, EFUSE_DIS_PAD_JTAG, and EFUSE_STRAP_JTAG_SEL that determine the JTAG signal source.

Table 2-8. JTAG Signal Source Selection

EFUSE_STRAP_JTAG_SEL	EFUSE_DIS_USB_JTAG	EFUSE_DIS_PAD_JTAG	JTAG Signal Source
1	0	0	Refer to Table 2-9
0	0	0	USB Serial/JTAG controller
don't care	0	1	USB Serial/JTAG controller
don't care	1	0	On-chip JTAG pins
don't care	1	1	N/A

To change the strapping bit values, users can apply the external pull-down/pull-up resistances, or use the host MCU's GPIOs to control the voltage level of these pins when powering on ESP32-S3.

After reset, the strapping pins work as normal-function pins.

Refer to Table 2-9 for a detailed configuration of the strapping pins.

Table 2-9. Strapping Pins

VDD_SPI Voltage					
Pin	Default	3.3 V	1.8 V		
GPIO45	Pull-down	0	1		
	Booting Mode ¹				
Pin	Default	SPI Boot	Download Boot		
GPIO0	Pull-up	1	0		
GPIO46	Pull-down	Don't care	0		

Enabling/Disabling ROM Messages Print During Booting ²						
Pin	Default	Enabled	Disabled			
GPIO46	Pull-down	See the 2nd note	See the 2nd note			
JTAG Signal Selection						
Pin	Default	EFUSE_DIS_USB_JTAG = 0, EFUSE_DIS_PAD_JTAG = 0,				
FIII	Delault	EFUSE_STRAP_JTAG_SEL=1				
GPIO3	N/A	0: JTAG signal from on-chip JTA	AG pins			
GI 103	IN/A	1: JTAG signal from USB Serial/JTAG controller				

Note:

- 1. The strapping combination of GPIO46 = 1 and GPIO0 = 0 is invalid and will trigger unexpected behavior.
- 2. By default, the ROM boot messages are printed over UART0 (U0TXD pin) and USB Serial/JTAG controller together. The ROM code printing can be disabled through configuration register and eFuse. For detailed information, please refer to Chapter Chip Boot Control in ESP32-S3 Technical Reference Manual.

VDD_SPI voltage is determined either by the strapping value of GPIO45 or by EFUSE_VDD_SPI_TIEH. When EFUSE_VDD_SPI_FORCE is 0, VDD_SPI voltage is determined by the strapping value of GPIO45; when EFUSE_VDD_SPI_FORCE is 1, VDD_SPI voltage is determined by EFUSE_VDD_SPI_TIEH. Please refer to the following table for default configurations:

Table 2-10. The Default Value for VDD_SPI Voltage

Chip Variant	EFUSE_VDD_SPI_FORCE	EFUSE_VDD_SPI_TIEH	VDD_SPI Voltage
ESP32-S3	0	0	Determined by GPIO45
ESP32-S3R2	1	1	Force to 3.3 V
ESP32-S3R8	1	1	Force to 3.3 V
ESP32-S3R8V	1	0	Force to 1.8 V
ESP32-S3FN8	1	1	Force to 3.3 V
ESP32-S3FH4R2	1	1	Force to 3.3 V

Figure 2-4 shows the setup and hold times for the strapping pin before and after the CHIP_PU signal goes high. Details about the parameters are listed in Table 2-11.

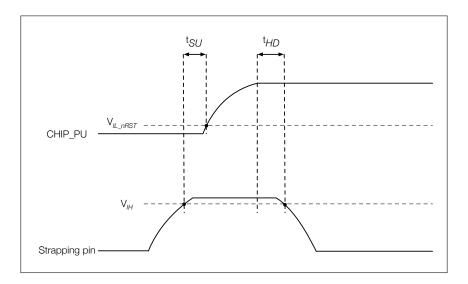


Figure 2-4. Setup and Hold Times for the Strapping Pin

Table 2-11. Parameter Descriptions of Setup and Hold Times for the Strapping Pin

Parameter	Description	Min (ms)
t_{SU}	Setup time before CHIP_PU goes from low to high	0
t_{HD}	Hold time after CHIP_PU goes high	3

3 Functional Description

This chapter describes the functional modules of ESP32-S3.

3.1 CPU and Memory

3.1.1 CPU

ESP32-S3 has a low-power Xtensa® dual-core 32-bit LX7 microprocessor with the following features:

- Five-stage pipeline that supports the clock frequency of up to 240 MHz
- 16-bit/24-bit instruction set providing high code density
- 32-bit customized instruction set and 128-bit data bus that provide high computing performance
- Support for single-precision floating-point unit (FPU)
- 32-bit multiplier and 32-bit divider
- Unbuffered GPIO instructions
- 32 interrupts at six levels
- Windowed ABI with 64 physical general registers
- Trace function with TRAX compressor, up to 16 KB trace memory
- JTAG for debugging

3.1.2 Internal Memory

ESP32-S3's internal memory includes:

- 384 KB ROM: for booting and core functions
- 512 KB on-chip SRAM: for data and instructions, running at a configurable frequency of up to 240 MHz
- RTC FAST memory: 8 KB SRAM that supports read/write/instruction fetch by the main CPU (LX7 dual-core processor). It can retain data in Deep-sleep mode
- RTC SLOW Memory: 8 KB SRAM that supports read/write/instruction fetch by the main CPU (LX7 dual-core processor) or coprocessors. It can retain data in Deep-sleep mode
- 4 Kbit eFuse: 1792 bits are reserved for user data, such as encryption key and device ID
- In-package flash and PSRAM: See details in Table 1-1 Comparison

3.1.3 External Flash and RAM

ESP32-S3 supports SPI, Dual SPI, Quad SPI, Octal SPI, QPI and OPI interfaces that allow connection to multiple external flash and RAM.

The external flash and RAM can be mapped into the CPU instruction memory space and read-only data memory space. The external RAM can also be mapped into the CPU data memory space. ESP32-S3 supports up to 1 GB of external flash and RAM, and hardware encryption/decryption based on XTS-AES to protect users' programs and data in flash and external RAM.

Through high-speed caches, ESP32-S3 can support at a time up to:

- External flash or RAM mapped into 32 MB instruction space as individual blocks of 64 KB
- External RAM mapped into 32 MB data space as individual blocks of 64 KB. 8-bit, 16-bit, 32-bit, and 128-bit reads and writes are supported. External flash can also be mapped into 32 MB data space as individual blocks of 64 KB, but only supporting 8-bit, 16-bit, 32-bit and 128-bit reads.

Note:

After ESP32-S3 is initialized, firmware can customize the mapping of external RAM or flash into the CPU address space.

3.1.4 Address Mapping Structure

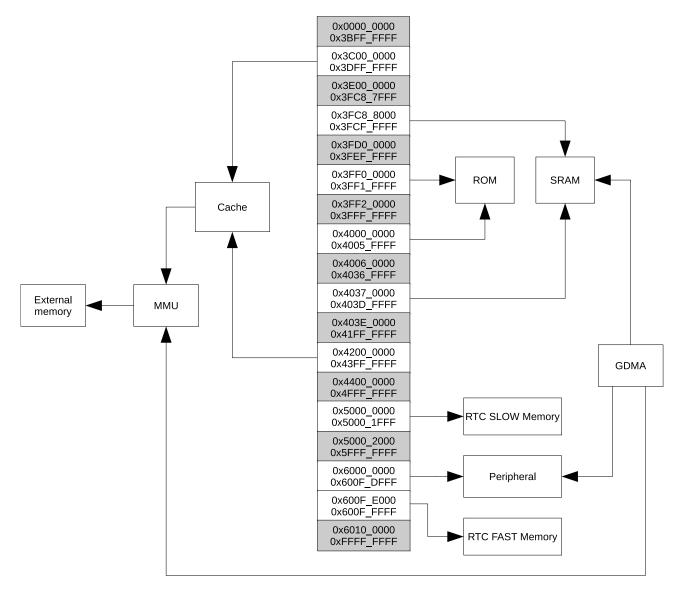


Figure 3-1. Address Mapping Structure

Note:

The memory space with gray background is not available to users.

3.1.5 Cache

ESP32-S3 has an instruction cache and a data cache shared by the two CPU cores. Each cache can be partitioned into multiple banks and has the following features:

- Instruction cache: 16 KB (one bank) or 32 KB (two banks)
 Data cache: 32 KB (one bank) or 64 KB (two banks)
- Instruction cache: four-way or eight-way set associative
 Data cache: four-way set associative
- Block size of 16 bytes or 32 bytes for both instruction cache and data cache
- Pre-load function
- Lock function
- · Critical word first and early restart

3.1.6 eFuse Controller

ESP32-S3 contains a 4-Kbit eFuse to store parameters, which are burned and read by an eFuse Controller. The eFuse Controller has the following features:

- 4 Kbits in total, with 1792 bits reserved for users, e.g., encryption key and device ID
- One-time programmable storage
- Configurable write protection
- Configurable read protection
- Various hardware encoding schemes to protect against data corruption

For detailed information, please refer to Chapter <u>eFuse Controller</u> in *ESP32-S3 Technical Reference Manual*.

3.1.7 Processor Instruction Extensions

The ESP32-S3 contains a series of new extended instruction set in order to improve the operation efficiency of specific AI and DSP (Digital Signal Processing) algorithms. The Processor Instruction Extensions (PIE) has the following features:

- 128-bit new general-purpose registers
- 128-bit vector operations, e.g., complex multiplication, addition, subtraction, multiplication, shifting, comparison, etc
- Data handling instructions and load/store operation instructions combined
- Non-aligned 128-bit vector data
- Saturation operation

RTC and Low-Power Management

Power Management Unit (PMU) 3.2.1

With the use of advanced power-management technologies, ESP32-S3 can switch between different power modes.

- Active mode: CPU and chip radio are powered on. The chip can receive, transmit, or listen.
- Modem-sleep mode: The CPU is operational and the clock speed can be reduced. The wireless baseband and radio are disabled, but wireless connection can remain active.
- Light-sleep mode: The CPU is paused. The RTC peripherals, as well as the ULP coprocessor can be woken up periodically by the timer. Any wake-up events (MAC, host, RTC timer, or external interrupts) will wake up the chip. Wireless connection can remain active. Users can optionally decide what peripherals to shut down/keep on (refer to Figure 0-1), for power-saving purpose.
- Deep-sleep mode: CPU and most peripherals are powered down. Only the RTC memory is powered on and RTC peripherals are optional. Wi-Fi connection data are stored in the RTC memory. The ULP coprocessor is functional.

For power consumption in different power modes, please refer to Table 4-8.

3.2.2 **Ultra-Low-Power Coprocessor**

The ULP coprocessor is designed as a simplified, low-power replacement of CPU in sleep modes. It can be also used to supplement the functions of the CPU in normal working mode. The ULP coprocessor and RTC memory remain powered on during the Deep-sleep mode. Hence, the developer can store a program for the ULP coprocessor in the RTC slow memory to access RTC GPIO, RTC peripheral devices, RTC timers and internal sensors in Deep-sleep mode.

ESP32-S3 has two ULP coprocessors, one based on RISC-V instruction set architecture (ULP-RISC-V) and the other on finite state machine (ULP-FSM). The clock of the coprocessors is the internal fast RC oscillator.

ULP-RISC-V has the following features:

- Support for RV32IMC instruction set
- Thirty-two 32-bit general-purpose registers
- 32-bit multiplier and divider
- Support for interrupts
- · Booted by the CPU, its dedicated timer, or RTC GPIO

ULP-FSM has the following features:

- · Support for common instructions including arithmetic, jump, and program control instructions
- Support for on-board sensor measurement instructions
- Booted by the CPU, its dedicated timer, or RTC GPIO

Note that these two coprocessors cannot work simultaneously.

3.3 Analog Peripherals

3.3.1 Analog-to-Digital Converter (ADC)

ESP32-S3 integrates two 12-bit SAR ADCs and supports measurements on 20 channels (analog-enabled pins). For power-saving purpose, the ULP coprocessors in ESP32-S3 can also be used to measure voltage in sleep modes. By using threshold settings or other methods, we can awaken the CPU from sleep modes.

3.3.2 Temperature Sensor

The temperature sensor generates a voltage that varies with temperature. The voltage is internally converted via an ADC into a digital value.

The temperature sensor has a range of –20 °C to 110 °C. It is designed primarily to sense the temperature changes inside the chip. The temperature value depends on factors such as microcontroller clock frequency or I/O load. Generally, the chip's internal temperature is higher than the ambient temperature.

3.3.3 Touch Sensor

ESP32-S3 has 14 capacitive-sensing GPIOs, which detect variations induced by touching or approaching the GPIOs with a finger or other objects. The low-noise nature of the design and the high sensitivity of the circuit allow relatively small pads to be used. Arrays of pads can also be used, so that a larger area or more points can be detected. The touch sensing performance can be further enhanced by the waterproof design and digital filtering feature.

3.4 System Components

3.4.1 Reset and Clock

ESP32-S3 provides four reset levels, namely CPU Reset, Core Reset, System Reset, and Chip Reset.

- Support four reset levels:
 - CPU Reset: only resets CPUx core. CPUx can be CPU0 or CPU1 here. Once such reset is released, programs will be executed from CPUx reset vector. Each CPU core has its own reset logic. If CPU Reset is from CPU0, the sensitive registers will be reset, too.
 - Core Reset: resets the whole digital system except RTC, including CPU0, CPU1, peripherals, Wi-Fi, Bluetooth® LE (BLE), and digital GPIOs.
 - System Reset: resets the whole digital system, including RTC.
 - Chip Reset: resets the whole chip.
- Support software reset and hardware reset:
 - Software reset is triggered by CPUx configuring its corresponding registers.
 - Hardware reset is directly triggered by the circuit.

For detailed information, please refer to Chapter Reset and Clock in ESP32-S3 Technical Reference Manual.

3.4.2 Interrupt Matrix

The interrupt matrix embedded in ESP32-S3 independently allocates peripheral interrupt sources to the two CPUs' peripheral interrupts, to timely inform CPU0 or CPU1 to process the interrupts once the interrupt signals are generated. The Interrupt Matrix has the following features:

- 99 peripheral interrupt sources as input
- Generate 26 peripheral interrupts to CPU0 and 26 peripheral interrupts to CPU1 as output. Note that the remaining six CPU0 interrupts and six CPU1 interrupts are internal interrupts.
- Disable CPU non-maskable interrupt (NMI) sources
- Query current interrupt status of peripheral interrupt sources

For detailed information, please refer to Chapter Interrupt Matrix (INTERRUPT) in ESP32-S3 Technical Reference Manual.

3.4.3 Permission Control

In ESP32-S3, the Permission Control module is used to control access to the slaves (including internal memory, peripherals, external flash and RAM). The host can access its slave only if it has the right permission. In this way, data and instructions are protected from illegitimate read or write.

The ESP32-S3 CPU can run in both Secure World and Non-secure World where independent permission controls are adopted. The Permission Control module is able to identify which World the host is running and then proceed with its normal operations.

The Permission Control module has the following features:

- Manage access to internal memory by:
 - CPU
 - CPU trace module
 - GDMA
- Manage access to external flash and RAM by:
 - MMU
 - SPI1
 - GDMA
 - CPU through Cache
- Manage access to peripherals, supporting
 - independent permission control for each peripheral
 - monitoring non-aligned access
 - access control for customized address range
- Integrate permission lock register
 - All permission registers can be locked with the permission lock register. Once locked, the permission register and the lock register cannot be modified, unless the CPU is reset.

- Integrate permission monitor interrupt
 - In case of illegitimate access, the permission monitor interrupt will be triggered and the CPU will be informed to handle the interrupt.

3.4.4 System Registers

ESP32-S3 system registers can be used to control the following peripheral blocks and core modules:

- System and memory
- Clock
- Software Interrupt
- Low-power management
- · Peripheral clock gating and reset
- CPU Control

For detailed information, please refer to Chapter <u>System Registers</u> in *ESP32-S3 Technical Reference Manual*.

3.4.5 GDMA Controller

ESP32-S3 has a general-purpose DMA controller (GDMA) with five independent channels for transmitting and another five independent channels for receiving. These ten channels are shared by peripherals that have DMA feature, and support dynamic priority.

The DMA controller controls data transfer using linked lists. It allows peripheral-to-memory and memory-to-memory data transfer at a high speed. All channels can access internal and external RAM.

The ten peripherals on ESP32-S3 with DMA feature are SPI2, SPI3, UHCI0, I2S0, I2S1, LCD/CAM, AES, SHA, ADC, and RMT.

For detailed information, please refer to Chapter <u>GDMA Controller (GDMA)</u> in *ESP32-S3 Technical Reference Manual*.

3.4.6 CPU Clock

The CPU clock has three possible sources:

- External main crystal clock
- Internal fast RC oscillator (typically about 17.5 MHz, and adjustable)
- PLL clock

The application can select the clock source from the three clocks above. The selected clock source drives the CPU clock directly, or after division, depending on the application. Once the CPU is reset, the default clock source would be the external main crystal clock divided by 2.

Note:

ESP32-S3 is unable to operate without an external main crystal clock.

For more information about clocks, please refer to Chapter Reset and Clock in ESP32-S3 Technical Reference Manual.

3.4.7 RTC Clock

The RTC slow clock is used for RTC counter, RTC watchdog and low-power controller. It has three possible sources:

- External low-speed (32 kHz) crystal clock
- Internal slow RC oscillator (typically about 136 kHz, and adjustable)
- Internal fast RC oscillator divided clock (derived from the internal fast RC oscillator divided by 256)

The RTC fast clock is used for RTC peripherals and sensor controllers. It has two possible sources:

- External main crystal clock divided by 2
- Internal fast RC oscillator (typically about 17.5 MHz, and adjustable)

3.4.8 Clock Glitch Detection

The Clock Glitch Detection module on ESP32-S3 monitors input clock signals from XTAL_CLK. If it detects a glitch with a width shorter than 3 ns, input clock signals from XTAL_CLK are blocked.

For more information, please refer to Chapter <u>Clock Glitch Detection</u> in *ESP32-S3 Technical Reference Manual*.

3.5 Digital Peripherals

3.5.1 IO MUX and GPIO Matrix

GPIO Matrix Features

- A full-switching matrix between the peripheral input/output signals and the GPIO pins
- 175 digital peripheral input signals can be sourced from the input of any GPIO pins
- The output of any GPIO pins can be from any of the 184 digital peripheral output signals
- · Supports signal synchronization for peripheral inputs based on APB clock bus
- Provides input signal filter
- Supports sigma delta modulated output
- Supports GPIO simple input and output

IO MUX Features

- Provides one configuration register IO_MUX_GPIOn_REG for each GPIO pin. The pin can be configured to
 - perform GPIO function routed by GPIO matrix.
 - or perform direct connection bypassing GPIO matrix.
- Supports some high-speed digital signals (SPI, JTAG, UART) bypassing GPIO matrix for better high-frequency digital performance. In this case, IO MUX is used to connect these pins directly to peripherals.

RTC IO MUX Features

- Controls low power feature of 22 RTC GPIO pins.
- Controls analog functions of 22 RTC GPIO pins.
- Redirects 22 RTC input/output signals to RTC system.

For more information, please refer to Chapter IO MUX and GPIO Matrix (GPIO, IO MUX) in ESP32-S3 Technical Reference Manual.

3.5.2 Serial Peripheral Interface (SPI)

ESP32-S3 features four SPI interfaces (SPI0, SPI1, SPI2 and SPI3). SPI0 and SPI1 can be configured to operate in SPI memory mode; SPI2 and SPI3 can be configured to operate in general-purpose SPI mode.

SPI Memory mode

In SPI memory mode, SPI0 and SPI1 interface with external SPI memory. Data transmission is in multiples of bytes. Up to 8-line SDR/DDR (Single Data Rate/Double Data Rate) reads and writes are supported. The clock frequency is configurable to a maximum of 120 MHz for OPI SDR/DDR mode.

SPI2 General-purpose SPI (GP-SPI) mode

SPI2 can operate in master and slave modes. The master mode supports two-line full-duplex communication and single-/two-/four-/eight-line half-duplex communication. The slave mode supports two-line full-duplex communication and single-/two-/four-line half-duplex communication. The host's clock frequency is configurable. Data transmission is in multiples of bytes. The clock polarity (CPOL) and phase (CPHA) are also configurable. The SPI2 interface supports DMA.

- In two-line full-duplex communication mode, the host's clock frequency is configurable to 80 MHz at most, and the slave's clock frequency to 60 MHz at most. Four modes of SPI transfer format are supported. Only SDR reads and writes are supported.
- In single-/two-/four-/eight-line half-duplex communication mode, the host's clock frequency is configurable to 80 MHz at most for SDR reads/writes and 40 MHz for DDR reads/writes. Four modes of SPI transfer format are supported.
- In single-/two-/four-line half-duplex communication mode, the slave's clock frequency is configurable to 60 MHz at most. Only SDR reads and writes are supported. Four modes of SPI transfer format are supported.

• SPI3 General-purpose SPI (GP-SPI) mode

SPI3 can operate in master and slave modes, in two-line full-duplex and single-line, two-line and four-line half-duplex communication modes. Only SDR reads and writes are supported. The host's clock frequency is configurable. Data transmission is in multiples of bytes. The clock polarity (CPOL) and phase (CPHA) are also configurable. The SPI3 interface supports DMA.

- In two-line full-duplex communication mode, the host's clock frequency is configurable to a maximum of 80 MHz, and the slave's clock frequency to a maximum of 60 MHz. Four modes of SPI transfer format are supported.
- In single-line, two-line and four-line half-duplex communication mode, the host's clock frequency is configurable to a maximum of 80 MHz, and the slave's clock frequency to 60 MHz at most. Four modes of SPI transfer format are supported.

In most cases, the data port connection between ESP32-S3 and external flash is as follows:

Table 3-1. Connection Between ESP32-S3 and External Flash

	External Flash Data Port						
Chip Pin	SPI Single-Line Mode	SPI Two-Line Mode	SPI Four-Line Mode	SPI Eight-Line Mode			
SPID (SPID)	DI	100	100	IO0			
SPIQ (SPIQ)	DO	IO1	IO1	IO1			
SPIWP (SPIWP)	WP#	_	102	IO2			
SPIHD (SPIHD)	HOLD#	_	IO3	IO3			
GPIO33	_	_	_	IO4			
GPIO34	_	_	_	IO5			
GPIO35	_	_	_	106			
GPIO36	_	_	_	107			
GPIO37	_	_	_	DQS			

3.5.3 LCD Interface

ESP32-S3 supports 8-bit ~16-bit parallel RGB, I8080, and MOTO6800 interfaces. These interfaces operate at 40 MHz or lower, and support conversion among RGB565, YUV422, YUV420, and YUV411.

3.5.4 Camera Interface

ESP32-S3 supports an 8-bit ~16-bit DVP image sensor, with clock frequency of up to 40 MHz. The camera interface supports conversion among RGB565, YUV422, YUV420, and YUV411.

3.5.5 UART Controller

ESP32-S3 has three UART (Universal Asynchronous Receiver Transmitter) controllers, i.e., UART0, UART1, and UART2, which support IrDA and asynchronous communication (RS232 and RS485) at a speed of up to 5 Mbps. Each UART Controller has the following features:

- Three clock sources that can be divided
- Programmable baud rate
- 1024 x 8-bit RAM shared by TX FIFOs and RX FIFOs of the three UART controllers
- Full-duplex asynchronous communication
- Automatic baud rate detection of input signals
- Data bits ranging from 5 to 8
- Stop bits of 1, 1.5, 2 or 3 bits
- Parity bit
- Special character AT_CMD detection
- RS485 protocol
- IrDA protocol
- High-speed data communication using GDMA

- UART as wake-up source
- Software and hardware flow control

For more information, please refer to Chapter UART Controller (UART) in ESP32-S3 Technical Reference Manual.

3.5.6 I2C Interface

ESP32-S3 has two I2C bus interfaces which are used for I2C master mode or slave mode, depending on the user's configuration. The I2C interfaces support:

- Standard mode (100 kbit/s)
- Fast mode (400 kbit/s)
- Up to 800 kbit/s (constrained by SCL and SDA pull-up strength)
- 7-bit and 10-bit addressing mode
- Double addressing mode (slave addressing and slave register addressing)

The hardware provides a command abstraction layer to simplify the usage of the I2C peripheral.

For more information, please refer to Chapter I2C Controller (I2C) in ESP32-S3 Technical Reference Manual.

3.5.7 **I2S Interface**

ESP32-S3 includes two standard I2S interfaces. They can operate in master mode or slave mode, in full-duplex mode or half-duplex communication mode, and can be configured to operate with an 8-bit, 16-bit, 24-bit, or 32-bit resolution as an input or output channel. BCK clock frequency, from 10 kHz up to 40 MHz, is supported.

The I2S interface has a dedicated DMA controller. It supports TDM PCM, TDM MSB alignment, TDM LSB alignment, TDM Phillips, and PDM interface.

3.5.8 Remote Control Peripheral

The RMT (Remote Control Peripheral) module is designed to send and receive infrared remote control signals. It has the following features:

- Four TX channels
- Four RX channels
- Support multiple channels (programmable) transmitting data simultaneously
- Eight channels share a 384 x 32-bit RAM
- Support modulation on TX pulses
- Support filtering and demodulation on RX pulses
- Wrap TX mode
- Wrap RX mode
- Continuous TX mode

- DMA access for TX mode on channel 3
- DMA access for RX mode on channel 7

For more information, please refer to Chapter Remote Control Peripheral (RMT) in ESP32-S3 Technical Reference Manual.

3.5.9 Pulse Count Controller

The pulse count controller captures pulse and counts pulse edges through multiple modes. It has the following features:

- Four independent pulse counters (units) that count from 1 to 65535
- Each unit consists of two independent channels sharing one pulse counter
- All channels have input pulse signals (e.g. sig_ch0_un) with their corresponding control signals (e.g. ctrl_ch0_un)
- Independently filter glitches of input pulse signals (sig_ch0_un and sig_ch1_un) and control signals (ctrl_ch0_un and ctrl_ch1_un) on each unit
- Each channel has the following parameters:
 - 1. Selection between counting on positive or negative edges of the input pulse signal
 - 2. Configuration to Increment, Decrement, or Disable counter mode for control signal's high and low states

For more information, please refer to Chapter Pulse Count Controller (PCNT) in ESP32-S3 Technical Reference Manual.

3.5.10 LED PWM Controller

The LED PWM controller can generate independent digital waveforms on eight channels. The LED PWM controller has the following features:

- · Can generate a digital waveform with configurable periods and duty cycle. The duty cycle resolution can be up to 14 bits within a 1 ms period.
- Has multiple clock sources, including APB clock and external main crystal clock.
- Can operate when the CPU is in Light-sleep mode.
- Supports gradual increase or decrease of duty cycle, which is useful for the LED RGB color-fading generator.

For more information, please refer to Chapter LED PWM Controller (LEDC) in ESP32-S3 Technical Reference Manual.

3.5.11 USB 2.0 OTG Full-Speed Interface

ESP32-S3 features a full-speed USB OTG interface along with an integrated transceiver. The USB OTG interface complies with the USB 2.0 specification. It has the following features:

General Features

• FS and LS data rates

- HNP and SRP as A-device or B-device
- Dynamic FIFO (DFIFO) sizing
- Multiple modes of memory access
 - Scatter/Gather DMA mode
 - Buffer DMA mode
 - Slave mode
- Can choose integrated transceiver or external transceiver
- Utilizing integrated transceiver with USB Serial/JTAG by time-division multiplexing when only integrated transceiver is used
- Support USB OTG using one of the transceivers while USB Serial/JTAG using the other one when both integrated transceiver or external transceiver are used

Device Mode Features

- Endpoint number 0 always present (bi-directional, consisting of EP0 IN and EP0 OUT)
- Six additional endpoints (endpoint numbers 1 to 6), configurable as IN or OUT
- Maximum of five IN endpoints concurrently active at any time (including EP0 IN)
- All OUT endpoints share a single RX FIFO
- Each IN endpoint has a dedicated TX FIFO

Host Mode Features

- 8 channels (pipes)
 - A control pipe consists of two channels (IN and OUT), as IN and OUT transactions must be handled separately. Only Control transfer type is supported.
 - Each of the other seven channels is dynamically configurable to be IN or OUT, and supports Bulk, Isochronous, and Interrupt transfer types.
- All channels share an RX FIFO, non-periodic TX FIFO, and periodic TX FIFO. The size of each FIFO is configurable.

For more information, please refer to Chapter <u>USB On-The-Go (USB)</u> in *ESP32-S3 Technical Reference Manual*.

3.5.12 USB Serial/JTAG Controller

ESP32-S3 integrates a USB Serial/JTAG controller that supports the following features:

- USB Full-speed device.
- Can be configured to either use internal USB PHY of ESP32-S3 or external PHY via GPIO matrix.
- Fixed function device, hardwired for CDC-ACM (Communication Device Class Abstract Control Model) and JTAG adapter functionality.
- 2 OUT Endpoints, 3 IN Endpoints in addition to Control Endpoint 0; Up to 64-byte data payload size.
- Internal PHY, so no or very few external components needed to connect to a host computer.

- CDC-ACM adherent serial port emulation is plug-and-play on most modern OSes.
- JTAG interface allows fast communication with CPU debug core using a compact representation of JTAG instructions.
- CDC-ACM supports host controllable chip reset and entry into download mode.

For more information, please refer to Chapter USB Serial/JTAG Controller (USB_SERIAL_JTAG) in ESP32-S3 Technical Reference Manual.

Motor Control PWM (MCPWM) 3.5.13

ESP32-S3 integrates two MCPWM that can be used to drive digital motors and smart light. Each MCPWM peripheral has one clock divider (prescaler), three PWM timers, three PWM operators, and a capture module. PWM timers are used for generating timing references. The PWM operators generate desired waveform based on the timing references. Any PWM operator can be configured to use the timing references of any PWM timers. Different PWM operators can use the same PWM timer's timing references to produce related PWM signals. PWM operators can also use different PWM timers' values to produce the PWM signals that work alone. Different PWM timers can also be synchronized together.

For more information, please refer to Chapter Motor Control PWM (MCPWM) in ESP32-S3 Technical Reference Manual.

3.5.14 SD/MMC Host Controller

ESP32-S3 has an SD/MMC Host Controller with the following features:

- Secure Digital (SD) memory version 3.0 and version 3.01
- Secure Digital I/O (SDIO) version 3.0
- Consumer Electronics Advanced Transport Architecture (CE-ATA) version 1.1
- Multimedia Cards (MMC version 4.41, eMMC version 4.5 and version 4.51)
- Up to 80 MHz clock output
- Three data bus modes:
 - 1-bit
 - 4-bit (supports two SD/SDIO/MMC 4.41 cards, and one SD card operating at 1.8 V in 4-bit mode)
 - 8-bit

For more information, please refer to Chapter SD/MMC Host Controller (SDHOST) in ESP32-S3 Technical Reference Manual.

3.5.15 TWAI® Controller

The Two-wire Automotive Interface (TWAI) is a multi-master, multi-cast communication protocol with error detection and signaling as well as inbuilt message priorities and arbitration. The TWAI controller in ESP32-S3 supports the following features:

- Compatible with ISO 11898-1 protocol (CAN Specification 2.0)
- Standard frame format (11-bit ID) and extended frame format (29-bit ID)

- Bit rates from 1 Kbit/s to 1 Mbit/s
- Multiple modes of operation:
 - Normal
 - Listen Only
 - Self-Test (no acknowledgment required)
- 64-byte receive FIFO
- Acceptance filter (single and dual filter modes)
- Error detection and handling:
 - Error counters
 - Configurable error interrupt threshold
 - Error code capture
 - Arbitration lost capture

For more information, please refer to Chapter Two-wire Automotive Interface (TWAI®) in ESP32-S3 Technical Reference Manual.

Radio and Wi-Fi 3.6

The ESP32-S3 radio consists of the following blocks:

- 2.4 GHz receiver
- 2.4 GHz transmitter
- Bias and regulators
- Balun and transmit-receive switch
- Clock generator

2.4 GHz Receiver 3.6.1

The 2.4 GHz receiver demodulates the 2.4 GHz RF signal to quadrature baseband signals and converts them to the digital domain with two high-resolution, high-speed ADCs. To adapt to varying signal channel conditions, ESP32-S3 integrates RF filters, Automatic Gain Control (AGC), DC offset cancelation circuits, and baseband filters.

2.4 GHz Transmitter 3.6.2

The 2.4 GHz transmitter modulates the quadrature baseband signals to the 2.4 GHz RF signal, and drives the antenna with a high-powered CMOS power amplifier. The use of digital calibration further improves the linearity of the power amplifier.

To compensate for receiver imperfections, additional calibration methods are built into the chip, including:

- Carrier leakage compensation
- I/Q amplitude/phase matching

- Baseband nonlinearities suppression
- RF nonlinearities suppression
- Antenna matching

These built-in calibration routines reduce the cost and time to the market for your product, and eliminate the need for specialized testing equipment.

3.6.3 Clock Generator

The clock generator produces quadrature clock signals of 2.4 GHz for both the receiver and the transmitter. All components of the clock generator are integrated into the chip, including inductors, varactors, filters, regulators, and dividers.

The clock generator has built-in calibration and self-test circuits. Quadrature clock phases and phase noise are optimized on chip with patented calibration algorithms which ensure the best performance of the receiver and the transmitter.

3.6.4 Wi-Fi Radio and Baseband

The ESP32-S3 Wi-Fi radio and baseband support the following features:

- 802.11b/g/n
- 802.11n MCS0-7 that supports 20 MHz and 40 MHz bandwidth
- 802.11n MCS32
- 802.11n 0.4 μ s guard-interval
- Data rate up to 150 Mbps
- RX STBC (single spatial stream)
- Adjustable transmitting power
- Antenna diversity:

ESP32-S3 supports antenna diversity with an external RF switch. This switch is controlled by one or more GPIOs, and used to select the best antenna to minimize the effects of channel imperfections.

3.6.5 Wi-Fi MAC

ESP32-S3 implements the full 802.11 b/g/n Wi-Fi MAC protocol. It supports the Basic Service Set (BSS) STA and SoftAP operations under the Distributed Control Function (DCF). Power management is handled automatically with minimal host interaction to minimize the active duty period.

The ESP32-S3 Wi-Fi MAC applies the following low-level protocol functions automatically:

- 4 × virtual Wi-Fi interfaces
- Simultaneous Infrastructure BSS Station mode, SoftAP mode, and Station + SoftAP mode
- RTS protection, CTS protection, Immediate Block ACK
- Fragmentation and defragmentation
- TX/RX A-MPDU, TX/RX A-MSDU

- TXOP
- WMM
- GCMP, CCMP, TKIP, WAPI, WEP, and BIP
- Automatic beacon monitoring (hardware TSF)
- 802.11mc FTM

3.6.6 Networking Features

Users are provided with libraries for TCP/IP networking, ESP-WIFI-MESH networking, and other networking protocols over Wi-Fi. TLS 1.2 support is also provided.

3.7 Bluetooth LE

ESP32-S3 includes a Bluetooth Low Energy subsystem that integrates a hardware link layer controller, an RF/modem block and a feature-rich software protocol stack. It supports the core features of Bluetooth 5 and Bluetooth mesh.

3.7.1 Bluetooth LE Radio and PHY

Bluetooth Low Energy radio and PHY in ESP32-S3 support:

- 1 Mbps PHY
- 2 Mbps PHY for high transmission speed and high data throughput
- Coded PHY for high RX sensitivity and long range (125 Kbps and 500 Kbps)
- Class 1 transmit power without external PA
- HW Listen before talk (LBT)

3.7.2 Bluetooth LE Link Layer Controller

Bluetooth Low Energy Link Layer Controller in ESP32-S3 supports:

- · LE advertising extensions, to enhance broadcasting capacity and broadcast more intelligent data
- Multiple advertisement sets
- · Simultaneous advertising and scanning
- Multiple connections in simultaneous central and peripheral roles
- Adaptive frequency hopping and channel assessment
- LE channel selection algorithm #2
- Connection parameter update
- High duty cycle non-connectable advertising
- LE privacy 1.2
- LE data packet length extension
- Link layer extended scanner filter policies

- · Low duty cycle directed advertising
- Link layer encryption
- LE Ping

3.8 **Timers and Watchdogs**

General Purpose Timers 3.8.1

ESP32-S3 is embedded with four 54-bit general-purpose timers, which are based on 16-bit prescalers and 54-bit auto-reload-capable up/down-timers.

The timers' features are summarized as follows:

- A 16-bit clock prescaler, from 2 to 65536
- A 54-bit time-base counter programmable to be incrementing or decrementing
- Able to read real-time value of the time-base counter
- · Halting and resuming the time-base counter
- Programmable alarm generation
- Timer value reload (Auto-reload at alarm or software-controlled instant reload)
- Level interrupt generation

For more information, please refer to Chapter Timer Group (TIMG) in ESP32-S3 Technical Reference Manual.

3.8.2 System Timer

ESP32-S3 integrates a 52-bit system timer, which has two 52-bit counters and three comparators. The system timer has the following features:

- Counters with a clock frequency of 16 MHz
- Three types of independent interrupts generated according to alarm value
- Two alarm modes: target mode and period mode
- 52-bit target alarm value and 26-bit periodic alarm value
- Read sleep time from RTC timer when the chip is awaken from Deep-sleep or Light-sleep mode
- Counters can be stalled if the CPU is stalled or in OCD mode

For more information, please refer to Chapter System Timer (SYSTIMER) in ESP32-S3 Technical Reference Manual.

3.8.3 Watchdog Timers

The ESP32-S3 contains three watchdog timers: one in each of the two timer groups (called Main System Watchdog Timers, or MWDT) and one in the RTC Module (called the RTC Watchdog Timer, or RWDT).

During the flash boot process, RWDT and the first MWDT are enabled automatically in order to detect and recover from booting errors.

Watchdog timers have the following features:

- Four stages, each with a programmable timeout value. Each stage can be configured, enabled and disabled separately
- Interrupt, CPU reset, or core reset for MWDT upon expiry of each stage; interrupt, CPU reset, core reset, or system reset for RWDT upon expiry of each stage
- 32-bit expiry counter
- · Write protection, to prevent RWDT and MWDT configuration from being altered inadvertently
- Flash boot protection
 If the boot process from an SPI flash does not complete within a predetermined period of time, the watchdog will reboot the entire main system.

For more information, please refer to Chapter Watchdog Timers in ESP32-S3 Technical Reference Manual.

3.8.4 XTAL32K Watchdog Timers

Interrupt and Wake-Up

When the XTAL32K watchdog timer detects the oscillation failure of XTAL32K_CLK, an oscillation failure interrupt RTC_XTAL32K_DEAD_INT (for interrupt description, please refer to <u>ESP32-S3 Technical Reference Manual</u>) is generated. At this point, the CPU will be woken up if in Light-sleep mode or Deep-sleep mode.

BACKUP32K_CLK

Once the XTAL32K watchdog timer detects the oscillation failure of XTAL32K_CLK, it replaces XTAL32K_CLK with BACKUP32K_CLK (with a frequency of 32 kHz or so) derived from RTC_CLK as RTC's SLOW_CLK, so as to ensure proper functioning of the system.

For more information, please refer to Chapter XTAL32K Watchdog Timers (XTWDT) in ESP32-S3 Technical Reference Manual.

3.9 Cryptography/Security Components

3.9.1 External Memory Encryption and Decryption

ESP32-S3 integrates an External Memory Encryption and Decryption module that complies with the XTS-AES standard. It supports the following features:

- General XTS_AES algorithm, compliant with IEEE Std 1619-2007
- Software-based manual encryption
- High-speed auto encryption, without software's participation
- High-speed auto decryption, without software's participation
- Encryption and decryption functions jointly determined by registers configuration, eFuse parameters, and boot mode

For more information, please refer to Chapter External Memory Encryption and Decryption (XTS_AES) in ESP32-S3 Technical Reference Manual.

3.9.2 Secure Boot

Secure Boot feature uses a hardware root of trust to ensure only signed firmware (with RSA-PSS signature) can be booted.

3.9.3 HMAC Accelerator

The Hash-based Message Authentication Code (HMAC) module computes Message Authentication Codes (MACs) using Hash algorithm and keys as described in RFC 2104. The HMAC Accelerator in ESP32-S3 supports the following features:

- Standard HMAC-SHA-256 algorithm
- Hash result only accessible by configurable hardware peripheral (in downstream mode)
- Compatible to challenge-response authentication algorithm
- Generates required keys for the Digital Signature (DS) peripheral (in downstream mode)
- Re-enables soft-disabled JTAG (in downstream mode)

For more information, please refer to Chapter <u>HMAC Accelerator (HMAC)</u> in *ESP32-S3 Technical Reference Manual*.

3.9.4 Digital Signature

A Digital Signature is used to verify the authenticity and integrity of a message using a cryptographic algorithm. The Digital Signature (DS) in ESP32-S3 supports the following features:

- RSA Digital Signatures with key length up to 4096 bits
- Encrypted private key data, only decryptable by DS peripheral
- SHA-256 digest to protect private key data against tampering by an attacker

For more information, please refer to Chapter <u>Digital Signature (DS)</u> in *ESP32-S3 Technical Reference Manual*.

3.9.5 World Controller

The ESP32-S3 can divide the hardware and software resources into a Secure World and a Non-Secure World to prevent sabotage or access to device information. Switching between the two worlds is performed by the World Controller, which supports the following features:

- Control of the CPU switching between secure and non-secure worlds
- Control of 15 DMA peripherals switching between secure and non-secure worlds
- Record of CPU's world switching logs
- Shielding of the CPU's NMI interrupt

3.9.6 SHA Accelerator

ESP32-S3 integrates an SHA accelerator, which is a hardware device that speeds up SHA algorithm significantly. The SHA Accelerator supports the following features:

All the hash algorithms introduced in FIPS PUB 180-4 Spec.

- SHA-1
- SHA-224
- SHA-256
- SHA-384
- SHA-512
- SHA-512/224
- SHA-512/256
- SHA-512/t
- Two working modes
 - Typical SHA
 - DMA-SHA
- interleaved function when working in Typical SHA working mode
- Interrupt function when working in DMA-SHA working mode

For more information, please refer to Chapter SHA Accelerator (SHA) in ESP32-S3 Technical Reference Manual.

AES Accelerator 3.9.7

ESP32-S3 integrates an Advanced Encryption Standard (AES) Accelerator, which is a hardware device that speeds up AES Algorithm significantly. The AES Accelerator supports the following features:

- Typical AES working mode
 - AES-128/AES-256 encryption and decryption
- DMA-AES working mode
 - AES-128/AES-256 encryption and decryption
 - Block cipher mode
 - * ECB (Electronic Codebook)
 - * CBC (Cipher Block Chaining)
 - * OFB (Output Feedback)
 - * CTR (Counter)
 - * CFB8 (8-bit Cipher Feedback)
 - * CFB128 (128-bit Cipher Feedback)
 - Interrupt on completion of computation

For more information, please refer to Chapter AES Accelerator (AES) in ESP32-S3 Technical Reference Manual.

3.9.8 RSA Accelrator

The RSA Accelerator provides hardware support for high precision computation used in various RSA asymmetric cipher algorithms. The RSA Accelerator in ESP32-S3 supports the following features:

- · Large-number modular exponentiation with two optional acceleration options
- Large-number modular multiplication
- Large-number multiplication
- Operands of different lengths
- Interrupt on completion of computation

For more information, please refer to Chapter RSA Accelrator (RSA) in ESP32-S3 Technical Reference Manual.

3.9.9 Random Number Generator

The random number generator in ESP32-S3 generates true random numbers, which means random number generated from a physical process, rather than by means of an algorithm. No number generated within the specified range is more or less likely to appear than any other number.

For more information, please refer to Chapter Random Number Generator (RNG) in ESP32-S3 Technical Reference Manual.

3.10 Peripheral Pin Configurations

Table 3-2. Peripheral Pin Configurations

Interface	Signal	Pin	Function
	ADC1_CH0	GPIO1	
	ADC1_CH1	GPIO2	
	ADC1_CH2	GPIO3	
	ADC1_CH3	GPIO4	
	ADC1_CH4	GPIO5	
	ADC1_CH5	GPIO6	
	ADC1_CH6	GPIO7	
	ADC1_CH7	GPIO8	
	ADC1_CH8	GPIO9	
ADC	ADC1_CH9	GPIO10	Two 12-bit SAR ADCs
ADC	ADC2_CH0	GPIO11	TWO 12-bit SALLADOS
	ADC2_CH1	GPIO12	
	ADC2_CH2	GPIO13	
	ADC2_CH3	GPIO14	
	ADC2_CH4	XTAL_32K_P	
	ADC2_CH5	XTAL_32K_N	
	ADC2_CH6	GPIO17	
	ADC2_CH7	GPIO18	
	ADC2_CH8	GPIO19	
	ADC2_CH9	GPIO20	

Interface	Signal	Pin	Function
	TOUCH1	GPIO1	
	TOUCH2	GPIO2	
	TOUCH3	GPIO3	
	TOUCH4	GPIO4	
Touch sensor	TOUCH5	GPIO5	
	TOUCH6	GPIO6	
	TOUCH7	GPIO7	Compositive toylob compose
	TOUCH8	GPIO8	Capacitive touch sensors
	TOUCH9	GPIO9	
	TOUCH10	GPIO10	
	TOUCH11	GPIO11	
	TOUCH12	GPIO12	
	TOUCH13	GPIO13	
	TOUCH14	GPIO14	
	MTDI	MTDI	
ITAO	MTCK	MTCK	ITAO for a official allowaria a
JTAG	MTMS	MTMS	JTAG for software debugging
	MTDO	MTDO	
	U0RXD_in		
	U0CTS_in		
	U0DSR_in		
	U0TXD_out		
	U0RTS_out		
	U0DTR_out		
	U1RXD_in		
	U1CTS_in		
LIADT	U1DSR_in	Any CDIO nino	Three UART devices with
UART	U1TXD_out	Any GPIO pins	hardware flow-control and DMA
	U1RTS_out		
	U1DTR_out		
	U2RXD_in		
	U2CTS_in		
	U2DSR_in		
	U2TXD_out		
	U2RTS_out		
	U2DTR_out		
	I2CEXT0_SCL_in/_out		
I2C	I2CEXT0_SDA_in/_out	Any CRIO since	Two I2C devices in slave or
IZU	I2CEXT1_SCL_in/_out	Any GPIO pins	master mode
	I2CEXT1_SDA_in/_out		
LED PWM	LEDC_LS_SIG_out0~7	Any GPIO pins	Eight independent channels.

Interface	Signal	Pin	Function		
	I2S0O_BCK_in				
	I2S0_MCLK_in				
	12S0O_WS_in				
	12S0I_SD_in				
	I2S0I_SD1_in				
	I2S0I_SD2_in				
	I2S0I_SD3_in				
	I2S0I_BCK_in				
	I2S0I_WS_in				
	I2S1O_BCK_in				
	I2S1_MCLK_in				
	I2S10_WS_in				
	I2S1I_SD_in				
100	I2S1I_BCK_in	A 0000	Stereo input and output from/to		
I2S	I2S1I_WS_in	Any GPIO pins	the audio codec		
	I2S0O_BCK_out				
	I2S0_MCLK_out				
	I2S0O_WS_out				
	I2S0O_SD_out				
	I2S0O_SD1_out				
	I2S0I_BCK_out				
	I2S0I_WS_out				
	I2S1O_BCK_out				
	I2S1_MCLK_out				
	I2S1O_WS_out				
	I2S1O_SD_out				
	I2S1I_BCK_out				
	I2S1I_WS_out				
	LCD_PCLK				
	LCD_DC				
	LCD_V_SYNC				
	LCD_H_SYNC				
	LCD_H_ENABLE				
	LCD_DATA_out0~15		8 ~16 data transmission to LCD		
LCD_CAMERA	LCD_CS	Any GPIO pins	interface and 8 ~16 data		
	CAM_CLK		reception by camera interface		
	CAM_V_SYNC				
	CAM_H_SYNC				
	CAM_H_ENABLE				
	CAM_PCLK				
	CAM_DATA_in0~15				
Remote Control	RMT_SIG_in0~3	Any CDIO pina	Four channels for an IR		
Peripheral	RMT_SIG_out0~3	Any GPIO pins	transceiver of various wave forms		

Interface	Signal	Pin	Function
	SPICLK_out_mux	SPICLK	
	SPICS0_out	SPICS0	
	SPICS1_out	SPICS1	
	SPID_in/_out	SPID	
	SPIQ_in/_out	SPIQ	Support Standard SPI, Dual SPI,
 SPI0/1	SPIWP_in/_out	SPIWP	QSPI, QPI, OSPI, and OPI that
01 10/ 1	SPIHD_in/_out	SPIHD	allow connection to external flash
	SPID4_in/_out	GPIO33	and RAM.
	SPID5_in/_out	GPIO34	
	SPID6_in/_out	GPIO35	
	SPID7_in/_out	GPIO36	
	SPIDQS_in/_out	GPIO37	
	FSPICLK_in/_out_mux		Support: • master mode of SPI, Dual
	FSPICS0_in/_out		SPI, Quad SPI,Octal SPI, QPI, and OPI, and slave
	FSPICS1~5_out		mode of SPI, Dual SPI, Quad SPI, and QPI;
	FSPID_in/_out		connection to external
SPI2	FSPIQ_in/_out	Any GPIO pins	flash, RAM, and other SPI devices;
	FSPIWP_in/_out		 four modes of SPI transfer format;
	FSPIHD_in/_out		• configurable SPI
	FSPIIO4~7_in/_out		frequency; • 64-byte FIFO or DMA
	FSPIDQS_out		buffer.
	SPI3_CLK_in/_out_mux		Support:
	SPI3_CS0_in/_out		 master and slave modes of
	SPI3_CS1_out		SPI, Dual SPI, Quad SPI,
0.7.1	SPI3_CS2_out		and QPI;
SPI3	SPI3_D_in/_out	Any GPIO pins	four modes of SPI transfer format:
	SPI3_Q_in/_out		format; • configurable frequency;
	SPI3_WP_in/_out		 64-byte FIFO or DMA
	SPI3_HD_in/_out		buffer.
	PCNT_SIG_CH0_in0~3		
	PCNT_SIG_CH1_in0~3		Capture pulse and count pulse
Pulse counter	PCNT_CTRL_CH0_in0~3	Any GPIO pins	edges in seven modes
	PCNT_CTRL_CH1_in0~3		

Interface	Signal	Pin	Function		
	D-	GPIO19 (for internal PHY)			
	D+	GPIO20 (for internal PHY)			
	VP	MTMS (for external PHY)	5 "		
LIOD OTO	VM	MTDI (for external PHY)	Full-speed USB OTG (USB OTG		
USB OTG	RCV	GPIO21 (for external PHY)	supports both full-speed on-chip		
	OEN	MTDO (for external PHY)	PHY and external PHY)		
	VPO	MTCK (for external PHY)			
	VMO	GPIO38 (for external PHY)			
	D-	GPIO19 (for internal PHY)			
	D+	GPIO20 (for internal PHY)	Flash programming and CPU		
USB	VP	MTMS (for external PHY)	debugging (USB Serial/JTAG		
Serial/JTAG	VM	MTDI (for external PHY)	controller supports both		
controller	OEN	MTDO (for external PHY)	full-speed on-chip PHY and		
	VPO	MTCK (for external PHY)	external PHY)		
	VMO	GPIO38 (for external PHY)			
	SDHOST_CCLK_out_1~2				
	SDHOST_RST_N_1~2				
	SD-				
	HOST_CCMD_OD_PULLUP_EN_N				
	SDIO_TOHOST_INT_out				
	SDHOST_CCMD_in/_out_1				
	SDHOST_CCMD_in/_out_2				
	SDHOST_CDATA_in/_out_10				
	SDHOST_CDATA_in/_out_11				
	SDHOST_CDATA_in/_out_12				
	SDHOST_CDATA_in/_out_13				
	SDHOST_CDATA_in/_out_14				
SD/MMC	SDHOST_CDATA_in/_out_15	Any GPIO pins	Secure Digital (SD) memory		
Host Controller	SDHOST_CDATA_in/_out_16	Arty GFIO pilis	version 3.0.1 supported		
	SDHOST_CDATA_in/_out_17				
	SDHOST_CDATA_in/_out_20				
	SDHOST_CDATA_in/_out_21				
	SDHOST_CDATA_in/_out_22				
	SDHOST_CDATA_in/_out_23				
	SDHOST_CDATA_in/_out_24				
	SDHOST_CDATA_in/_out_25				
	SDHOST_CDATA_in/_out_26				
	SDHOST_CDATA_in/_out_27				
	SDHOST_DATA_STROBE_1~2				
	SDHOST_CARD_DETECT_N_1~2				
	SD-				
	HOST_CARD_WRITE_PRT_1~2				
	SDHOST_CARD_INT_N_1~2				

Interface	Signal	Pin	Function		
	PWM0_SYNC0~2_in				
	PWM0_F0~2_in				
	PWM0_CAP0~2_in				
	PWM1_SYNC0~2_in				
	PWM1_F0~2_in				
	PWM1_CAP0~2_in		Two MCPWM input and output		
	PWM0_out0a		pins. Signals include PWM		
MCPWM	PWM0_out0b		differential output signals, fault		
	PWM0_out1a	Any GPIO pins	input signals to be detected,		
	PWM0_out1b	Arry dr 10 pins	input signals to be captured, and		
	PWM0_out2a		external clock synchronization		
	PWM0_out2b		signals		
	PWM1_out0a		Signais		
	PWM1_out0b				
	PWM1_out1a				
	PWM1_out1b				
	PWM1_out2a				
	PWM1_out2b				
	TWAI_RX		Compatible with ISO 11898-1		
TWAI®	TWAI_TX	Any GPIO pins	protocol (CAN Specification 2.0).		
Controller	TWAI_BUS_OFF_ON	Arry Or 10 pins	Data rate up to 1 Mbit/s		
	TWAI_CLKOUT		Data rate up to 1 Mibit/5		

Electrical Characteristics

4.1 **Absolute Maximum Ratings**

Stresses beyond the absolute maximum ratings listed in the table below may cause permanent damage to the device. These are stress ratings only, and do not refer to the functional operation of the device.

Table 4-1. Absolute Maximum Ratings

Symbol	Parameter	Min	Max	Unit
VDDA, VDD3P3, VDD3P3_RTC,	Voltage applied to power supply pins	0.0	3.6	\/
VDD3P3_CPU, VDD_SPI	per power domain	-0.3 3.6		\ \ \
l _{output} *	Cumulative IO output current		1500	mA
T_{STORE}	Storage temperature	-40	150	°C

^{*} The chip worked properly after a 24-hour test in ambient temperature at 25 °C, and the IOs in three domains (VDD3P3_RTC, VDD3P3_CPU, VDD_SPI) output high logic level to ground.

Recommended Operating Conditions

Table 4-2. Recommended Operating Conditions

Symbol	Parameter		Min	Тур	Max	Unit
VDDA, VDD3P3	Voltage applie	ed to power supply	3.0	3.3	3.6	V
VDD3P3_RTC	pins per powe	er domain	3.0	ა.ა	3.0	V
VDD_SPI (working as			1.8	3.3	3.6	V
input power supply) 1	_		1.0	ა.ა	3.0	V
VDD3P3_CPU ^{2, 3}	Voltage applie	Voltage applied to power supply pin		3.3	3.6	V
I_{VDD}^{4}	Current delive	Current delivered by external power supply		_		А
		ESP32-S3			105	
	Ambient	ESP32-S3FN8			85	
T_A	temperature	ESP32-S3R2	-40	-40 —	85	°C
		ESP32-S3R8 ⁵			65	
		ESP32-S3R8V ⁵			65	

¹ For more information, please refer to Section 2.7 *Power Scheme*.

² When writing to eFuses, VDD3P3_CPU should not exceed 3.3 V.

³ When VDD_SPI is used to drive peripherals, VDD3P3_CPU should comply with the peripherals' specifications. For more information, please refer to Table 4-3.

⁴ If you use a single power supply, the recommended output current is 500 mA or more.

⁵ For ESP32-S3R8 and ESP32-S3R8V chips, if the PSRAM ECC function is enabled, the maximum ambient temperature can be improved to 85 °C, while the usable size of PSRAM will be reduced by 1/16.

4.3 VDD_SPI Output Characteristics

Table 4-3. VDD_SPI Output Characteristics

Symbol	Parameter	Тур	Unit
R_{SPI}	On-resistance in 3.3 V mode	14	Ω
I_{SPI}	Output current in 1.8 V mode	40	mA

In real-life applications, when VDD_SPI works in 3.3 V output mode, VDD3P3_CPU may be affected by R_{SPI}. For example, when VDD3P3_CPU is used to drive a 3.3 V flash, it should comply with the following specifications:

 $VDD3P3_CPU > VDD_flash_min + I_flash_max*R_{SPI}$

Among which, VDD_flash_min is the minimum operating voltage of the flash, and I_flash_max the maximum current.

For more information, please refer to section 2.7 Power Scheme.

DC Characteristics (3.3 V, 25 °C) 4.4

Table 4-4. DC Characteristics (3.3 V, 25 °C)

Symbol	Parameter	Min	Тур	Max	Unit
C_{IN}	Pin capacitance	_	2	_	рF
V_{IH}	High-level input voltage	$0.75 \times VDD^1$	_	VDD ¹ + 0.3	V
V_{IL}	Low-level input voltage	-0.3	_	$0.25 \times VDD^1$	V
$ \cdot _{IH}$	High-level input current	_	_	50	nA
_{IL}	Low-level input current	_	_	50	nA
V_{OH}^2	High-level output voltage	$0.8 \times VDD^1$	_	_	V
V_{OL}^2	Low-level output voltage	_	_	$0.1 \times VDD^1$	V
1.	High-level source current (VDD 1 = 3.3 V, V $_{OH}$		40		mA
$ \cdot _{OH}$	>= 2.64 V, PAD_DRIVER = 3)	_	40		ША
Lar	Low-level sink current (VDD 1 = 3.3 V, V $_{OL}$ =		28		mA
$ I_{OL} $	0.495 V, PAD_DRIVER = 3)	_	20		ША
R_{PU}	Internal weak pull-up resistor	_	45	_	$k\Omega$
R_{PD}	Internal weak pull-down resistor	_	45	_	$k\Omega$
V	Chip reset release voltage (CHIP_PU voltage is	0.75 × VDD ¹		VDD ¹ + 0.3	V
V_{IH_nRST}	within the specified range)	0.73 X VDD	_	VDD + 0.3	V
V	Chip reset voltage (CHIP_PU voltage is within	-0.3		0.25 × VDD ¹	V
V_{IL_nRST}	the specified range)		0.20 × VDD	V	

¹ VDD is the I/O voltage for a particular power domain of pins.

 $^{^{2}}$ V_{OH} and V_{OL} are measured using high-impedance load.

4.5 **ADC Characteristics**

Table 4-5. ADC Characteristics

Symbol	Parameter	Min	Max	Unit
DNL (Differential nonlinearity) ¹	ADC connected to an external	1	1	LSB
DNE (Differential Horillinearity)	100 nF capacitor; DC signal input;	-4	4	LOD
IN II. (Indeed, and in a self-self-self-self-self-self-self-self-	Ambient temperature at 25 °C;	-8	8	LSB
INL (Integral nonlinearity)	Wi-Fi off	-0	0	LOD
Sampling rate	_	_	100	kSPS ²

¹ To get better DNL results, you can sample multiple times and apply a filter, or calculate the average value.

ESP-IDF provides couple of calibration methods for ADC. Results after calibration using hardware + software calibration are shown in Table 4-6. For higher accuracy, users may apply other calibration methods provided in ESP-IDF, or implement their own.

Table 4-6. ADC Calibration Results

Parameter	Description	Min	Max	Unit
Total error	ATTEN0, effective measurement range of 0 ~ 950	-5	5	mV
	ATTEN1, effective measurement range of 0 ~ 1250	-6	6	mV
	ATTEN2, effective measurement range of 0 ~ 1750	-10	10	mV
	ATTEN3, effective measurement range of 0 ~ 3100	-50	50	mV

Current Consumption 4.6

4.6.1 RF Current Consumption in Active Mode

The current consumption measurements are taken with a 3.3 V supply at 25 °C of ambient temperature at the RF port. All transmitters' measurements are based on a 100% duty cycle.

Table 4-7. Wi-Fi Current Consumption Depending on RF Modes

Work Mode ¹	Des	cription	Peak (mA)
TX		802.11b, 1 Mbps, @21 dBm	340
		802.11g, 54 Mbps, @19 dBm	291
Active (RF working)	1.	802.11n, HT20, MCS7, @18.5 dBm	283
		802.11n, HT40, MCS7, @18 dBm	286
RX		802.11b/g/n, HT20	88
		802.11n, HT40	91

¹ The CPU work mode: Single core runs 32-bit data access instructions at 80 MHz, the other core is in idle state.

² kSPS means kilo samples-per-second.

Current Consumption in Other Modes

The measurements below are applicable to ESP32-S3 and ESP32-S3FH8. Since ESP32-S3R2, ESP32-S3R8, ESP32-S3R8V, and ESP32-S3FN4R2 are embedded with PSRAM, their current consumption might be higher. Please refer to the table note for detailed information.

Table 4-8. Current Consumption in Low-Power Modes

Work mode	Description	Typ (μ A)
Light-sleep	VDD_SPI and Wi-Fi are powered down, and all GPIOs are high-impedance.	240 ¹
Doop aloop	RTC memory and RTC peripherals are powered on.	8
Deep-sleep	RTC memory is powered on. RTC peripherals are powered off.	7
Power off	CHIP_PU is set to low level. The chip is powered off.	1

¹ In Light-sleep mode, all related SPI pins are pulled up. For chips embedded with PSRAM, please add corresponding PSRAM consumption values, e.g., 140 μ A for 8 MB 8-line PSRAM (3.3 V), 200 μ A for 8 MB 8-line PSRAM (1.8 V) and 40 μ A for 2 MB 4-line PSRAM (3.3 V).

Table 4-9. Current Consumption in Modem-sleep Mode

Frequency		Typ ¹	Typ ²
(MHz)	Description	(mA)	(mA)
	WAITI (Dual core in idle state)	13.2	18.8
	Single core running 32-bit data access instructions, the other core in idle state	16.2	21.8
40	Dual core running 32-bit data access instructions	18.7	24.4
	Single core running 128-bit data access instructions, the other core in idle state	19.9	25.4
	Dual core running 128-bit data access instructions	23.0	28.8
	WAITI	22.0	36.1
	Single core running 32-bit data access instructions, the other core in idle state	(mA) (mA) 13.2 18.8 16.2 21.8 18.7 24.4 19.9 25.4 23.0 28.8 22.0 36.1 28.4 42.6 33.1 47.3 35.1 49.6 41.8 56.3 27.6 42.3 39.9 54.6 49.6 64.1 54.4 69.2 66.7 81.1 32.9 47.6	
80	Dual core running 32-bit data access instructions	33.1	47.3
	Single core running 128-bit data access instructions, the other core in idle state	35.1	49.6
	Dual core running 128-bit data access instructions	41.8	56.3
	WAITI	27.6	42.3
	Single core running 32-bit data access instructions, the other core in idle state	39.9	54.6
160	Dual core running 32-bit data access instructions	49.6	64.1
	Single core running 128-bit data access instructions, the other core in idle state	54.4	69.2
	Dual core running 128-bit data access instructions	66.7	81.1
	WAITI	32.9	47.6
	Single core running 32-bit data access instructions, the other core in idle state	51.2	65.9
240	Dual core running 32-bit data access instructions	66.2	81.3
	(MHz) 40 80	WAITI (Dual core in idle state) Single core running 32-bit data access instructions, the other core in idle state 40 Dual core running 128-bit data access instructions Single core running 128-bit data access instructions, the other core in idle state Dual core running 128-bit data access instructions WAITI Single core running 32-bit data access instructions, the other core in idle state 80 Dual core running 32-bit data access instructions Single core running 128-bit data access instructions, the other core in idle state Dual core running 128-bit data access instructions WAITI Single core running 32-bit data access instructions, the other core in idle state Dual core running 32-bit data access instructions, the other core in idle state 160 Dual core running 32-bit data access instructions Single core running 128-bit data access instructions, the other core in idle state Dual core running 128-bit data access instructions, the other core in idle state Dual core running 32-bit data access instructions WAITI Single core running 32-bit data access instructions, the other core in idle state	WAITI (Dual core in idle state) Single core running 32-bit data access instructions, the other core in idle state Dual core running 128-bit data access instructions, the other core in idle state Dual core running 128-bit data access instructions, the other core in idle state Dual core running 128-bit data access instructions WAITI Single core running 32-bit data access instructions, the other core in idle state Dual core running 32-bit data access instructions, the other core in idle state 80 Dual core running 32-bit data access instructions Single core running 128-bit data access instructions, the other core in idle state Dual core running 128-bit data access instructions WAITI Single core running 32-bit data access instructions, the other core in idle state Dual core running 32-bit data access instructions, the other core in idle state Dual core running 32-bit data access instructions, the other core in idle state Dual core running 128-bit data access instructions, the other core in idle state Dual core running 128-bit data access instructions, the other core in idle state Dual core running 128-bit data access instructions, the other core in idle state Dual core running 32-bit data access instructions, the other core in idle state Dual core running 32-bit data access instructions, the other core in idle state Dual core running 32-bit data access instructions 66.7 WAITI Single core running 32-bit data access instructions, the other core in idle state

Table 4-9 - cont'd from previous page

Work mode	Frequency (MHz)	Description	Typ ¹ (mA)	Typ ² (mA)
		Single core running 128-bit data access instructions, the other core in idle state	72.4	87.9
		Dual core running 128-bit data access instructions	91.7	107.9

¹ Current consumption when all peripheral clocks are **disabled**.

Reliability 4.7

Table 4-10. Reliability Qualifications

Test Item	Test Conditions	Test Standard	
HTOL (High Temperature	 125 °C, 1000 hours	JESD22-A108	
Operating Life)	120 0, 1000 110010	020022 71100	
ESD (Electro-Static	HBM (Human Body Mode) ¹ ± 2000 V	JS-001	
Discharge Sensitivity)	CDM (Charge Device Mode) ² ± 1000 V	JS-002	
Latch up	Current trigger ± 200 mA	JESD78	
Laterrup	Voltage trigger $1.5 \times VDD_{max}$	JESDIO	
	Bake 24 hours @125 °C	J-STD-020, JESD47,	
Preconditioning	Moisture soak (level 3: 192 hours @30 °C, 60% RH)	JESD22-A113	
	IR reflow solder: 260 + 0 °C, 20 seconds, three times	JLSD22-ATTS	
TCT (Temperature Cycling	_65 °C / 150 °C, 500 cycles	JESD22-A104	
Test)	-03 07 130 0, 300 cycles	JLSD22-A104	
uHAST (Highly			
Accelerated Stress Test,	130 °C, 85% RH, 96 hours	JESD22-A118	
unbiased)			
HTSL (High Temperature	150 °C 1000 bours	JESD22-A103	
Storage Life)	150 °C, 1000 hours	JLODZZ-ATUO	
LTSL (Low Temperature	-40 °C, 1000 hours	JESD22-A119	
Storage Life)	-40 O, 1000 Hours	JLODZZ-ATT9	

¹ JEDEC document JEP155 states that 500 V HBM allows safe manufacturing with a standard ESD control process.

² Current consumption when all peripheral clocks are **enabled**. In practice, the current consumption might be different depending on which peripherals are enabled.

³ In Modem-sleep mode, Wi-Fi is clock gated, and the current consumption might be higher when accessing flash. For a flash rated at 80 Mbit/s, in SPI 2-line mode the consumption is 10 mA.

² JEDEC document JEP157 states that 250 V CDM allows safe manufacturing with a standard ESD control process.

4.8 Wi-Fi Radio

Table 4-11. Wi-Fi Frequency

Parameter	Min	Typ	Max
	(MHz)	(MHz)	(MHz)
Center frequency of operating channel	2412	_	2484

4.8.1 Wi-Fi RF Transmitter (TX) Specifications

Table 4-12. TX Power with Spectral Mask and EVM Meeting 802.11 Standards

	Min	Тур	Max
Rate	(dBm)	(dBm)	(dBm)
802.11b, 1 Mbps	_	21.0	_
802.11b, 11 Mbps	_	21.0	_
802.11g, 6 Mbps	_	20.5	
802.11g, 54 Mbps	_	19.0	_
802.11n, HT20, MCS0	_	19.5	_
802.11n, HT20, MCS7	_	18.5	_
802.11n, HT40, MCS0		19.5	_
802.11n, HT40, MCS7	_	18.0	_

Table 4-13. TX EVM Test

	Min	Тур	SL ¹
Rate	(dB)	(dB)	(dB)
802.11b, 1 Mbps, @21 dBm	_	-24.5	-10
802.11b, 11 Mbps, @21 dBm	_	-24.5	-10
802.11g, 6 Mbps, @20.5 dBm	_	-21.5	-5
802.11g, 54 Mbps, @19 dBm	_	-28.0	-25
802.11n, HT20, MCS0, @19.5 dBm	_	-23.0	-5
802.11n, HT20, MCS7, @18.5 dBm	_	-29.5	-27
802.11n, HT40, MCS0, @19.5 dBm	_	-23.0	-5
802.11n, HT40, MCS7, @18 dBm	_	-29.5	-27

¹ SL stands for standard limit value.

4.8.2 Wi-Fi RF Receiver (RX) Specifications

Table 4-14. RX Sensitivity

	Min	Тур	Max
Rate	(dBm)	(dBm)	(dBm)
802.11b, 1 Mbps	_	-98.4	_
802.11b, 2 Mbps		-95.4	
802.11b, 5.5 Mbps	_	-93.0	
802.11b, 11 Mbps	_	-88.6	_
802.11g, 6 Mbps		-93.2	_
802.11g, 9 Mbps		-91.8	
802.11g, 12 Mbps		-91.2	_
802.11g, 18 Mbps		-88.6	_
802.11g, 24 Mbps	_	-86.0	_
802.11g, 36 Mbps	_	-82.4	_
802.11g, 48 Mbps	_	-78.2	_
802.11g, 54 Mbps	_	-76.5	_
802.11n, HT20, MCS0	_	-92.6	_
802.11n, HT20, MCS1	_	-91.0	_
802.11n, HT20, MCS2	_	-88.2	_
802.11n, HT20, MCS3	_	-85.0	_
802.11n, HT20, MCS4	_	-81.8	_
802.11n, HT20, MCS5	_	-77.4	_
802.11n, HT20, MCS6	_	-75.8	_
802.11n, HT20, MCS7	_	-74.2	_
802.11n, HT40, MCS0	_	-90.0	_
802.11n, HT40, MCS1	_	-88.0	_
802.11n, HT40, MCS2		-85.2	_
802.11n, HT40, MCS3	_	-82.0	_
802.11n, HT40, MCS4	_	-79.0	_
802.11n, HT40, MCS5	_	-74.4	_
802.11n, HT40, MCS6	_	-72.8	_
802.11n, HT40, MCS7	_	-71.4	_

Table 4-15. Maximum RX Level

	Min	Тур	Max
Rate	(dBm)	(dBm)	(dBm)
802.11b, 1 Mbps	_	5	_
802.11b, 11 Mbps	_	5	_
802.11g, 6 Mbps	_	5	_
802.11g, 54 Mbps	_	0	_
802.11n, HT20, MCS0	_	5	_

Table 4-15 – cont'd from previous page

	Min	Тур	Max
Rate	(dBm)	(dBm)	(dBm)
802.11n, HT20, MCS7	_	0	_
802.11n, HT40, MCS0	_	5	_
802.11n, HT40, MCS7	_	0	_

Table 4-16. RX Adjacent Channel Rejection

	Min	Тур	Max
Rate	(dB)	(dB)	(dB)
802.11b, 1 Mbps	_	35	
802.11b, 11 Mbps	_	35	_
802.11g, 6 Mbps	_	31	_
802.11g, 54 Mbps	_	20	_
802.11n, HT20, MCS0	_	31	_
802.11n, HT20, MCS7	_	16	_
802.11n, HT40, MCS0		25	_
802.11n, HT40, MCS7	_	11	_

4.9 Bluetooth LE Radio

Table 4-17. Bluetooth LE Frequency

	Min	Тур	Max
Parameter	(MHz)	(MHz)	(MHz)
Center frequency of operating channel	2402	_	2480

4.9.1 Bluetooth LE RF Transmitter (TX) Specifications

Table 4-18. Transmitter Characteristics - Bluetooth LE 1 Mbps

Parameter	Description	Min	Тур	Max	Unit
RF transmit power	RF power control range	-24.00	0	21.00	dBm
ni transmit power	Gain control step	_	3.00	_	dB
	$ Max _{n=0,\ 1,\ 2,\k}$	_	2.50		kHz
Carrier frequency offset and drift	$Max \left f_0 - f_n \right $	_	2.00	_	kHz
Carrier frequency offset and drift	$Max \left f_{n-} f_{n-5} \right $	_	1.39		kHz
	$ f_1 - f_0 $	_	0.80	_	kHz
	$\Deltaf1_{ ext{avg}}$	_	249.00		kHz
Modulation characteristics	Min Δ $f2_{\rm max}$ (for at least		198.00		kHz
INIOGUIATION CHARACTERISTICS	99.9% of all Δ $f2_{\rm max}$)	_	190.00	_	NI IZ
	$\Delta~f2_{\mathrm{avg}}/\Delta~f1_{\mathrm{avg}}$	_	0.86		_

Table 4-18 – cont'd from previous page

Parameter	Description	Min	Тур	Max	Unit
	±2 MHz offset	_	-37.00	_	dBm
In-band spurious emissions	±3 MHz offset	_	-42.00		dBm
	>±3 MHz offset	_	-44.00		dBm

Table 4-19. Transmitter Characteristics - Bluetooth LE 2 Mbps

Parameter	Description	Min	Тур	Max	Unit
RF transmit power	RF power control range	-24.00	0	21.00	dBm
ni transmit power	Gain control step	_	3.00	_	dB
			2.50	_	kHz
Carrier frequency offset and drift	$ Max f_0 - f_n $	_	1.90	_	kHz
Carrier frequency offset and drift	$ \operatorname{Max} f_{n-} f_{n-5} $	_	1.40	_	kHz
	$ f_1 - f_0 $	_	1.10	_	kHz
	$\Delta f1_{avg}$		499.00	_	kHz
Modulation characteristics	Min Δ $f2_{\rm max}$ (for at least		416.00		kHz
iviodulation characteristics	99.9% of all Δ $f2_{\text{max}}$)	_	410.00	_	KI IZ
	$\Delta f 2_{\rm avg}/\Delta f 1_{\rm avg}$	_	0.89	_	_
	±4 MHz offset	_	-43.80	_	dBm
In-band spurious emissions	±5 MHz offset	_	-45.80	_	dBm
	>±5 MHz offset	_	-47.00	_	dBm

Table 4-20. Transmitter Characteristics - Bluetooth LE 125 Kbps

Parameter	Description	Min	Тур	Max	Unit
RF transmit power	RF power control range	-24.00	0	21.00	dBm
ni transmit power	Gain control step	_	3.00		dB
	$ Max _{n=0,1,2,k}$	_	0.80		kHz
Carrier frequency offset and drift	$Max f_0 - f_n $	_	0.98		kHz
Carrier frequency offset and drift	$ f_n - f_{n-3} $	_	0.30	_	kHz
	$ f_0 - f_3 $		1.00		kHz
	$\Delta~f1_{ ext{avg}}$	_	248.00		kHz
Modulation characteristics	Min $\Delta \ f1_{ m max}$ (for at least		222.00		kHz
	99.9% of all $\Delta f1_{\text{max}}$)	_	222.00	_	KI IZ
	±2 MHz offset	_	-37.00	_	dBm
In-band spurious emissions	±3 MHz offset	_	-42.00	_	dBm
	>±3 MHz offset	_	-44.00		dBm

Table 4-21. Transmitter Characteristics - Bluetooth LE 500 Kbps

Parameter	Description	Min	Тур	Max	Unit
RF transmit power	RF power control range	-24.00	0	21.00	dBm
ni transmit power	Gain control step	_	3.00	_	dB

Table 4-21 - cont'd from previous page

Parameter	Description	Min	Тур	Max	Unit
			0.70	_	kHz
Carrier frequency offset and drift	$ Max f_0 - f_n $		0.90	_	kHz
Carrier frequency offset and drift	$ f_{n}-f_{n-3} $		0.85	_	kHz
	$ f_0 - f_3 $	_	0.34	_	kHz
	$\Delta f 2_{avg}$	_	213.00		kHz
Modulation characteristics	Min Δ $f2_{\rm max}$ (for at least		196.00		kHz
	99.9% of all Δ $f2_{\text{max}}$)	_	190.00		KI IZ
	±2 MHz offset	_	-37.00		dBm
In-band spurious emissions	±3 MHz offset	_	-42.00	_	dBm
	>±3 MHz offset	_	-44.00	_	dBm

4.9.2 Bluetooth LE RF Receiver (RX) Specifications

Table 4-22. Receiver Characteristics - Bluetooth LE 1 Mbps

Parameter	Description	Min	Тур	Max	Unit
Sensitivity @30.8% PER	_	_	-97.5	_	dBm
Maximum received signal @30.8% PER	_	_	8	_	dBm
Co-channel C/I	F = F0 MHz	_	9	_	dB
	F = F0 + 1 MHz	_	-3	_	dB
	F = F0 - 1 MHz	_	-3	_	dB
	F = F0 + 2 MHz	_	-28	_	dB
Adjacent channel selectivity C/I	F = F0 - 2 MHz	_	-30	_	dB
Adjacent channel selectivity C/1	F = F0 + 3 MHz	_	-31	_	dB
	F = F0 - 3 MHz	_	-33	_	dB
	F > F0 + 3 MHz	_	-32	_	dB
	F > F0 – 3 MHz	_	-36	_	dB
Image frequency	_	_	-32	_	dB
Adjacent channel to image frequency	$F = F_{image} + 1 \text{ MHz}$	_	-39	_	dB
Adjacent channel to image frequency	$F = F_{image} - 1 \text{ MHz}$	_	-31	_	dB
	30 MHz ~ 2000 MHz	_	-9	_	dBm
Out-of-band blocking performance	2003 MHz ~ 2399 MHz	_	-19	_	dBm
	2484 MHz ~ 2997 MHz	_	-16	_	dBm
	3000 MHz ~ 12.75 GHz	_	-5	_	dBm
Intermodulation	_	_	-31	_	dBm

Table 4-23. Receiver Characteristics - Bluetooth LE 2 Mbps

Parameter	Description	Min	Тур	Max	Unit
Sensitivity @30.8% PER	_	_	-93.5	_	dBm
Maximum received signal @30.8% PER	_	_	3	_	dBm
Co-channel C/I	F = F0 MHz	_	10	_	dB
	F = F0 + 2 MHz	_	-8	_	dB
	F = F0 – 2 MHz	_	-5	_	dB
	F = F0 + 4 MHz		-31	_	dB
Adjacent channel selectivity C/I	F = F0 – 4 MHz	_	-33	_	dB
Adjacent channel selectivity C/1	F = F0 + 6 MHz	_	-37	_	dB
	F = F0 – 6 MHz	_	-37	_	dB
	F > F0 + 6 MHz	_	-40		dB
	F > F0 - 6 MHz	_	-40	_	dB
Image frequency	_	_	-31		dB
Adjacent channel to image frequency	$F = F_{image} + 2 MHz$	_	-37	_	dB
Adjacent channel to image frequency	$F = F_{image} - 2 \text{ MHz}$	_	-8	_	dB
	30 MHz ~ 2000 MHz	_	-16	_	dBm
Out-of-band blocking performance	2003 MHz ~ 2399 MHz	_	-20	_	dBm
	2484 MHz ~ 2997 MHz	_	-16	_	dBm
	3000 MHz ~ 12.75 GHz	_	-16	_	dBm
Intermodulation	_		-30		dBm

Table 4-24. Receiver Characteristics - Bluetooth LE 125 Kbps

Parameter	Description	Min	Тур	Max	Unit
Sensitivity @30.8% PER	_	_	-104.5	_	dBm
Maximum received signal @30.8% PER	_	_	8	_	dBm
Co-channel C/I	F = F0 MHz	_	6	_	dB
	F = F0 + 1 MHz	_	-6	_	dB
	F = F0 – 1 MHz	_	-5	_	dB
	F = F0 + 2 MHz	_	-32	_	dB
Adjacent channel selectivity C/I	F = F0 - 2 MHz	_	-39	_	dB
Adjacent channel selectivity C/1	F = F0 + 3 MHz	_	-35	_	dB
	F = F0 - 3 MHz	_	-45	_	dB
	F > F0 + 3 MHz	_	-35	_	dB
	F > F0 – 3 MHz	_	-48	_	dB
Image frequency	_	_	-35	_	dB
Adia and about all to impact functions	$F = F_{image} + 1 \text{ MHz}$	_	-49	_	dB
Adjacent channel to image frequency	$F = F_{image} - 1 \text{ MHz}$	_	-32		dB

Table 4-25. Receiver Characteristics - Bluetooth LE 500 Kbps

Parameter	Description	Min	Тур	Max	Unit
Sensitivity @30.8% PER	_	_	-101	_	dBm
Maximum received signal @30.8% PER	_	_	8	_	dBm
Co-channel C/I	F = F0 MHz	_	4	_	dB
	F = F0 + 1 MHz	_	-5	_	dB
	F = F0 – 1 MHz	_	-5	_	dB
	F = F0 + 2 MHz	_	-28	_	dB
Adjacent channel selectivity C/I	F = F0 – 2 MHz	_	-36	_	dB
Adjacent channel selectivity C/1	F = F0 + 3 MHz	_	-36	_	dB
	F = F0 - 3 MHz	_	-38	_	dB
	F > F0 + 3 MHz	_	-37	_	dB
	F > F0 – 3 MHz	_	-41	_	dB
Image frequency	_	_	-37	_	dB
A discount of a constant in a	$F = F_{image} + 1 \text{ MHz}$	_	-44	_	dB
Adjacent channel to image frequency	$F = F_{image} - 1 \text{ MHz}$	_	-28	_	dB

Packaging

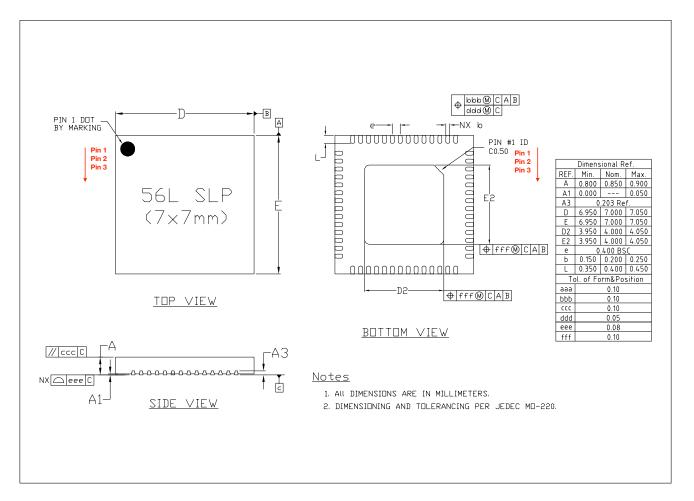


Figure 5-1. QFN56 (7×7 mm) Package

Note:

- The pins of the chip are numbered in an anti-clockwise direction from Pin 1 in the top view.
- For information about tape, reel, and product marking, please refer to Espressif Chip Packaging Information.

6 Related Documentation and Resources

Related Documentation

- ESP32-S3 Technical Reference Manual Detailed information on how to use the ESP32-S3 memory and peripherals.
- ESP32-S3 Hardware Design Guidelines Guidelines on how to integrate the ESP32-S3 into your hardware product.
- · Certificates
 - https://espressif.com/en/support/documents/certificates
- ESP32-S3 Advisories Information on security, bugs, compatibility, component reliability.
 - https://espressif.com/en/support/documents/advisories
- Documentation Updates and Update Notification Subscription https://espressif.com/en/support/download/documents

Developer Zone

- ESP-IDF Programming Guide for ESP32-S3 Extensive documentation for the ESP-IDF development framework.
- ESP-IDF and other development frameworks on GitHub.
 - https://github.com/espressif
- ESP32 BBS Forum Engineer-to-Engineer (E2E) Community for Espressif products where you can post questions, share knowledge, explore ideas, and help solve problems with fellow engineers.
 - https://esp32.com/
- The ESP Journal Best Practices, Articles, and Notes from Espressif folks.
 - https://blog.espressif.com/
- See the tabs SDKs and Demos, Apps, Tools, AT Firmware.
 - https://espressif.com/en/support/download/sdks-demos

Products

- ESP32-S3 Series SoCs Browse through all ESP32-S3 SoCs.
 - https://espressif.com/en/products/socs?id=ESP32-S3
- ESP32-S3 Series Modules Browse through all ESP32-S3-based modules.
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Revision History

Date	Version	Release notes
2022-09	v1.3	 Added a note about the maximum ambient temperature of R8 series chips to Table 1-1 and Table 4-2 Added information about power-up glitches for some pins in Section 2.5 Added the information about VDD3P3 power pins to Table 2-2 and Section 2.7 Updated section 3.7.1 Added the fourth note in Table 2-1 Updated the minimum and maximum values of Bluetooth LE RF transmit power in Section 4.9.1 Other minor updates
2022-07	v1.2	 Updated description of ROM code printing in Section 2.8 Updated Figure 0-1 Update Section 4.6 Deleted the hyperlinks in Application
2022-04	v1.1	 Synchronized eFuse size throughout Updated pin description in Table 2-1 Updated SPI resistance in Table 4-3 Added information about chip ESP32-S3FH4R2
2022-01	v1.0	 Added wake-up sources for Deep-sleep mode Added Table 2-10 for default configurations of VDD_SPI Added ADC calibration results in Table 4-6 Added typical values when all peripherals and peripheral clocks are enabled to Table 4-9 Added more descriptions of modules/peripherals in Section 3 Updated Figure 0-1 Updated JEDEC specification Updated Wi-Fi RF data in Section 4.6 Updated temperature for ESP32-S3R8 and ESP32-S3R8V Updated description of Deep-sleep mode in Table 4-8 Updated wording throughout
2021-10-12	v0.6.1	Updated text description

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Date	Version	Release notes
2021-09-30	v0.6	 Updated to chip revision 1 by swapping pin 53 and pin 54 (XTAL_P and XTAL_N) Updated Figure 0-1 Added CoreMark score in section Features Updated Section 2.8 Added data for cumulative IO output current in Table 4-1 Added data for Modem-sleep current consumption in Table 4-9 Updated data in section 4.6, 4.8, and 4.9 Updated wording throughout
2021-07-19	v0.5.1	 Added "for chip revision 0" on cover, in footer and watermark to indicate that the current and previous versions of this datasheet are for chip version 0 Corrected a few typos
2021-07-09	v0.5	Preliminary version



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